



HY17P51

Datasheet

8-Bit RISC-like Mixed Signal Microcontroller
Embedded 4x14 LCD Driver
Embedded High Resolution $\Sigma\Delta$ ADC

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1. Features

- 8-Bit RISC-like microcontrollers with 71 high-performance instruction set H08D (same as H08A), support C compiler
- Operating voltage and operating temperature range
 - VDD : 2.0V ~ 5.5V
 - VDDA : 2.4V ~ 5.0V
 - -40°C ~ 85°C
- Internal High Precision RC Oscillator, Many CPU clock rates enable users to have the most power-saving plan.
 - Active mode
 - Idle mode
 - Sleep mode
- Memory
 - 4K words OTP program memory
 - 256 bytes data memory
 - Support 8 stack level
- Reset
 - Power On Reset
 - Brown Out Reset
 - Watch Dog Reset
 - Stack Over Reset
- 4 X 14 LCD Driver
 - 1/4 Duty 1/3 Bias
 - Built-in charge pump regulated circuit providing 8 LCD bias voltage
 - 2 SEG ports can set as digital input and output
- LVD low voltage detection function has 14 steps of voltage detection configuration and external input voltage detection function
- VDDA has 10mA regulated voltage source output, wtuw fast start function to provide sensor driving voltage.
- 24-Bit Σ ADC
 - Built-in PGA (Programmable Gain Amplifier) 1/4x \ 1/2x \ 1x. ...128x
 - Zero point bias translation controller
 - Sampling frequency 921KHz
 - Settable over-sampling rate is 64~65536
 - Diverse data output rate. Max. 7.1Ksps
 - Built-in absolute temperature sensor
- Timer
 - Watch Dog
 - ◆ Reset event
 - ◆ Interrupt event
 - 1 channels 8-bit Timer A1
 - ◆ Interrupt event
 - ◆ Compare events
- 64 words Built-In EPROM (BIE), 2.75V low voltage programming control circuit
- Interface
 - 1 channels serial communication EUART module
- Package
 - QFN16
 - QFN32

Function List

Model No.	VDD (V)	Internal Clock (Hz)	System Clock (Hz)	Program Memory (word)	SRAM (byte)	BIE (byte)	ADC ENOB (bit x ch)	Sample Rate (sps)	LCD (com x seg)	I/O	Timer (bit x ch)	PWM (bit x ch)	Serial Interface (I/F x ch)	Package
HY17P51	2.0~5.5	14.5K	14.5K ~ 8M	4K	256	64LV	20-bit x4	8~7.1K	-	8	8-bit x 1	-	EUART	QFN16
		1.843M							4 x 14					QFN32
		3.686M												
		7.834M												

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2. Pin Definition

2.1. QFN32 Pin Diagram

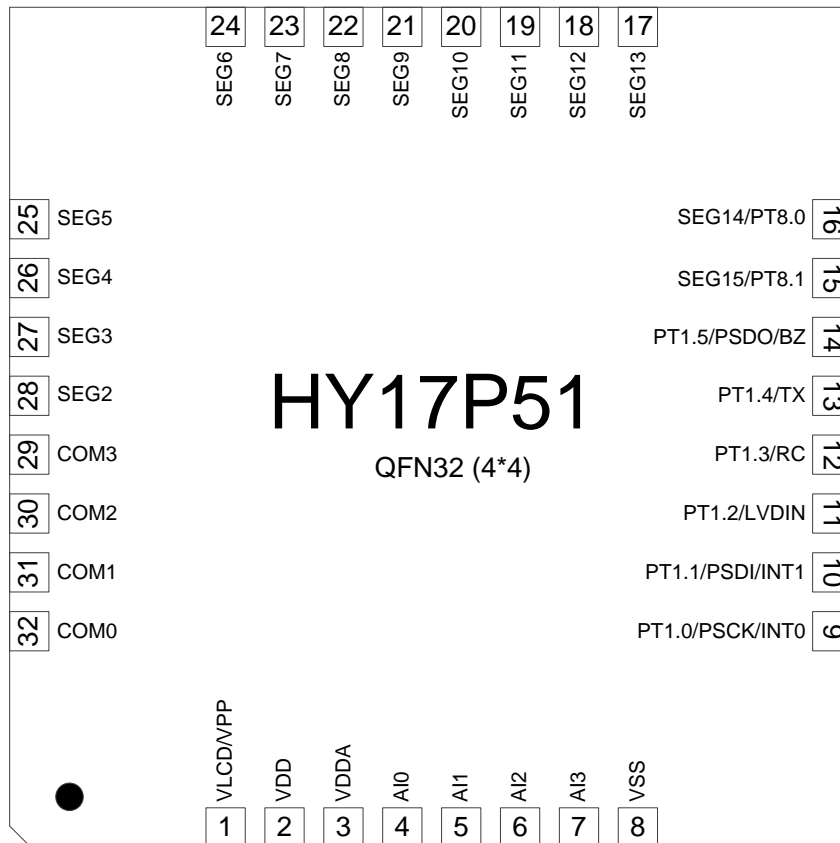


Figure 2-1 QFN32 Pin Diagram

Note: VPP and VLCD reuse the same PIN, input of high voltage is prohibited when OTP is not burned

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2.2. QFN16 Pin Diagram

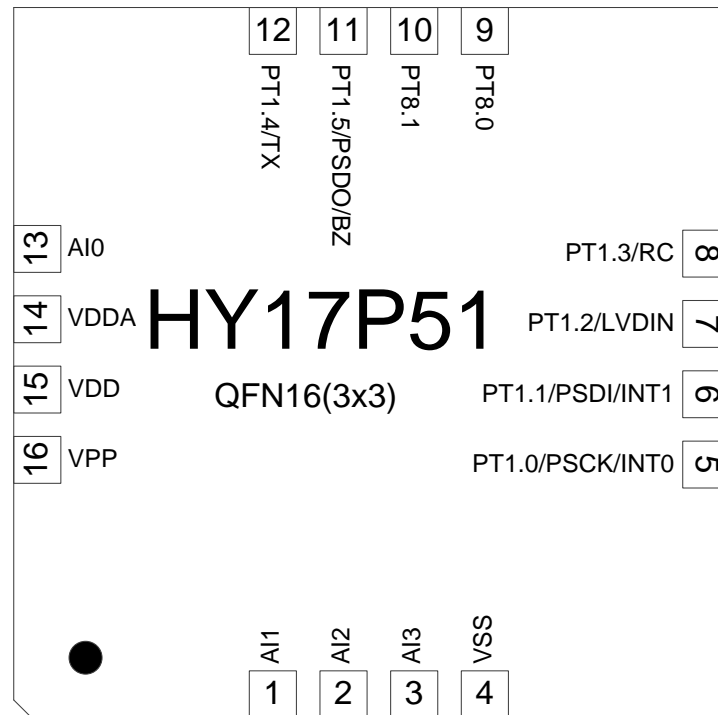


Figure 2-2 QFN16 Pin Diagram

Note: VPP and VLCD reuse the same PIN, input of high voltage is prohibited when OTP is not burned

2.3. Pinout I/O Description

"I/O" Input/Output, "I" Input, "O" Output, "S" Smith triggers, "C" CMOS, "P" Power Source, "A" Analog channel

Package / Pin No.		Pin Name	Characteristic		Description
QFN32 (4x4)	QFN16 (3x3)		Type	Buffer	
1	16	VLCD/VPP			
		VLCD	P	P	Power Source of LCD
		VPP	P	P	OTP burning voltage source input pin
2	15	VDD	P	P	Chip Power Voltage Input, an external 1~10uF capacitor is required.
3	14	VDDA	P	P	LDO output, Analog circuit voltage source, an external 1~10uF capacitor is required. (source: VDD)
4	13	AI0	A	A	Analog input channel 0
5	1	AI1	A	A	Analog input channel 1
6	2	AI2	A	A	Analog input channel 2
7	3	AI3	A	A	Analog input channel 3
8	4	VSS	P	P	System Power Ground
9	5	PT1.0/INT1.0/PSCK			
		PT1.0	I/O	S/C	Digital input / Output pin
		INT1.0	I	S	External interrupt source input pin
		PSCK	I	S	OTP read / write interface pin, PSCK
10	6	PT1.1/INT1.1/PSDI			
		PT1.1	I/O	S/C	Digital input / Output pin
		INT1.1	I	S	External interrupt source input pin
		PSDI	I	S	OTP read / write interface pin, PSDI
11	7	PT1.2/LVDIN			
		PT1.2	I/O	S/C	Digital input / Output pin
		LVDIN	A	A	LVD external signal input port
12	8	PT1.3/RC			
		PT1.3	I/O	S/C	Digital input / Output pin
		RC	I	S	RC pin of EUART interface
13	12	PT1.4/TX			
		PT1.4	I/O	S/C	Digital input / Output pin
		TX	O	C	TX pin of EUART interface
14	11	PT1.5/PSDO/BZ			
		PT1.5	I/O	S/C	Digital input / Output pin
		PSDO	O	C	OTP read / write interface pin, PSDO
		BZ	O	C	Buzzer Signal Output pin

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Package / Pin No.		Pin Name	Characteristic		Description
QFN32 (4x4)	QFN16 (3x3)		Type	Buffer	
15	10	PT8.1/SEG15	I/O	S/C	Digital input / Output pin LCD Segment Output pin
		PT8.1 SEG15	O	A	
16	9	PT8.0/SEG14	I/O	S/C	Digital input / Output pin LCD Segment Output pin
		PT8.0 SEG14	O	A	
17	-	SEG13	O	A	LCD Segment Output pin
18	-	SEG12	O	A	LCD Segment Output pin
19	-	SEG11	O	A	LCD Segment Output pin
20	-	SEG10	O	A	LCD Segment Output pin
21	-	SEG9	O	A	LCD Segment Output pin
22	-	SEG8	O	A	LCD Segment Output pin
23	-	SEG7	O	A	LCD Segment Output pin
24	-	SEG6	O	A	LCD Segment Output pin
25	-	SEG5	O	A	LCD Segment Output pin
26	-	SEG4	O	A	LCD Segment Output pin
27	-	SEG3	O	A	LCD Segment Output pin
28	-	SEG2	O	A	LCD Segment Output pin
29	-	COM3	O	A	LCD COM Output pin
30	-	COM2	O	A	LCD COM Output pin

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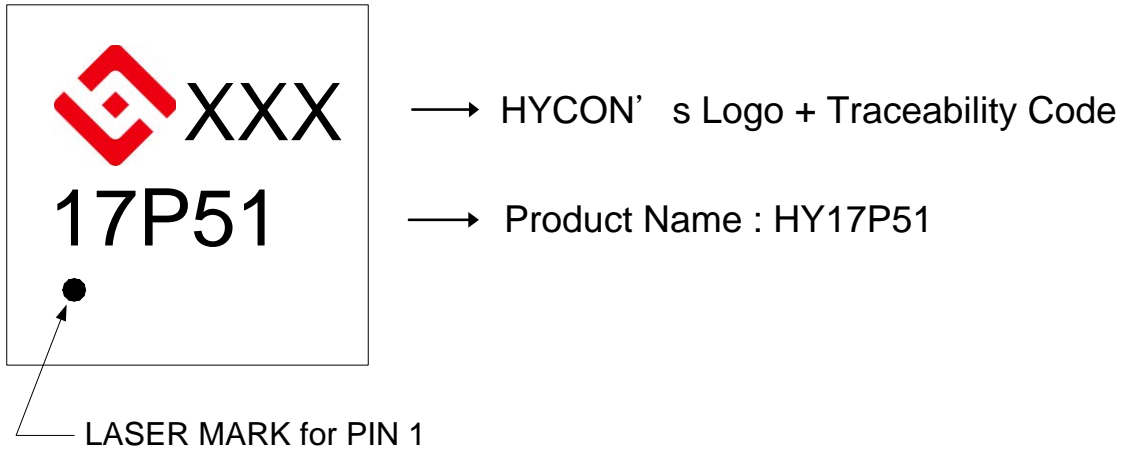
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Package / Pin No.		Pin Name	Characteristic		Description
QFN32 (4x4)	QFN16 (3x3)		Type	Buffer	
31	-	COM1 COM1	O	A	LCD COM Output pin
32	-	COM0 COM0	O	A	LCD COM Output pin

Table 2-1 Pin Definition and Function Description

2.4. Package marking information

2.4.1. QFN Package marking information



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3. Application Circuit

3.1. Bridge Sensor with LCD display

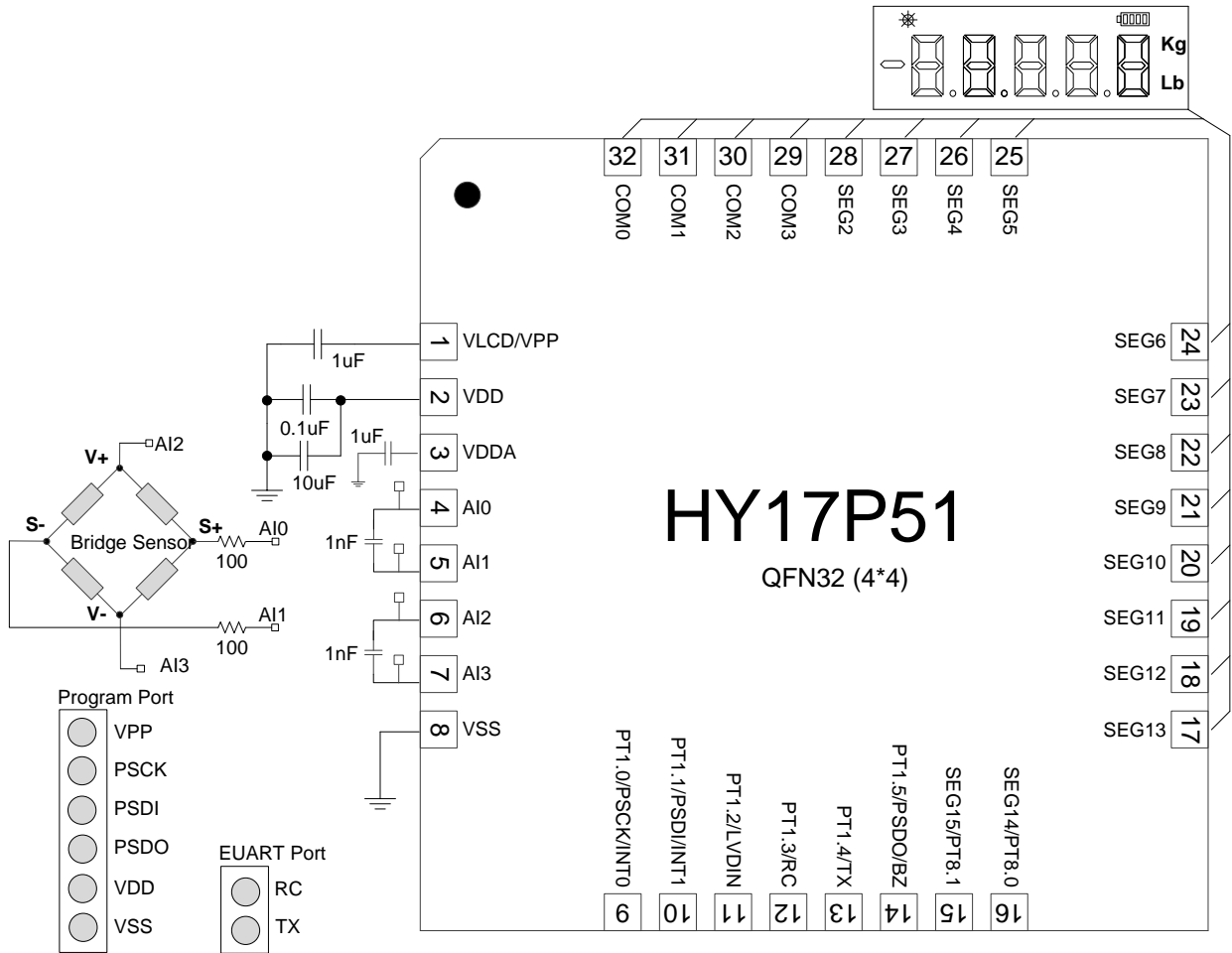


Figure 3-1 Bridge Sensor application reference circuit

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3.2. Digital Thermometer with LCD display

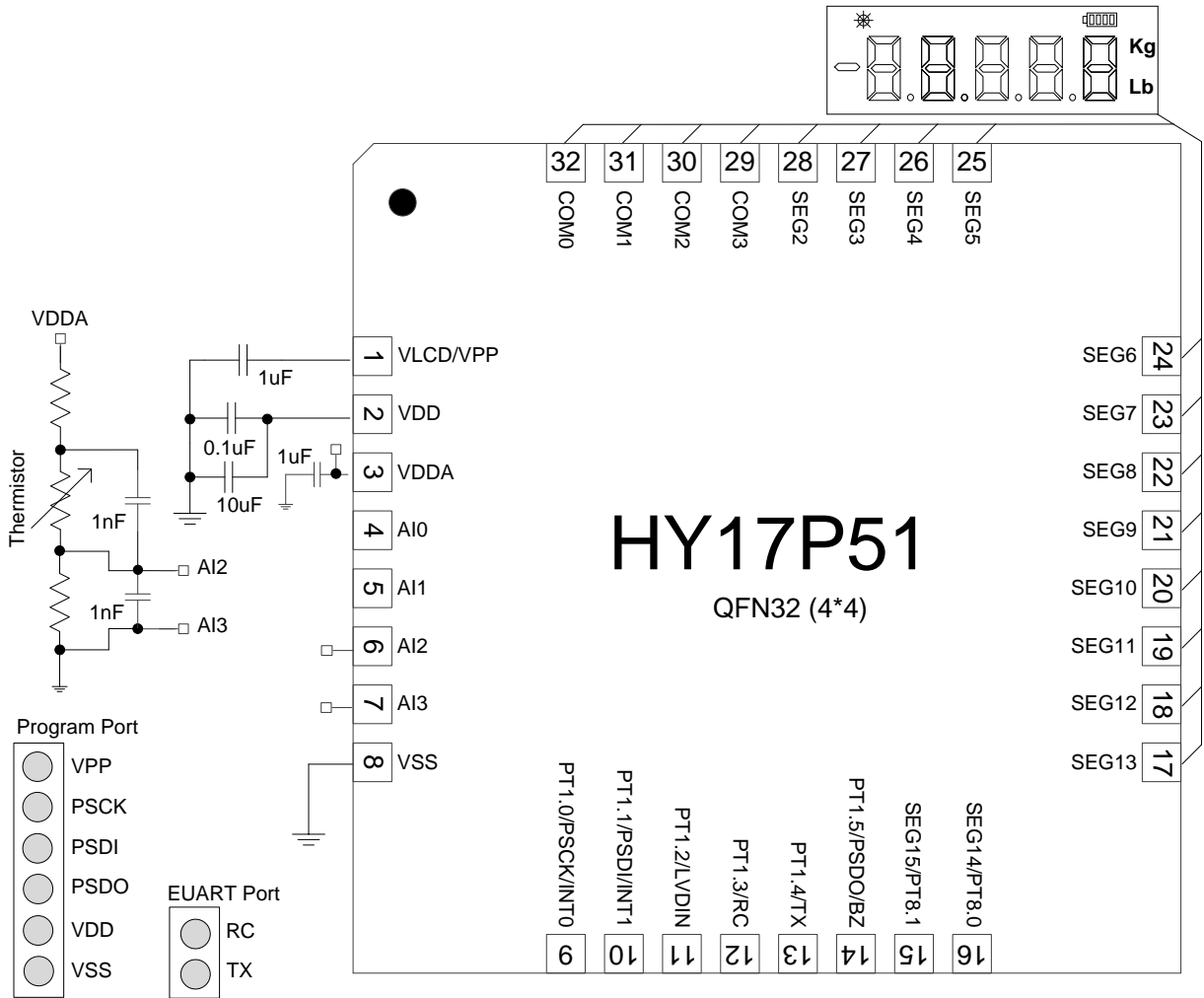


Figure 3-2 Digital Thermometer application reference circuit

4. Function Outline

4.1. Internal Block Diagram

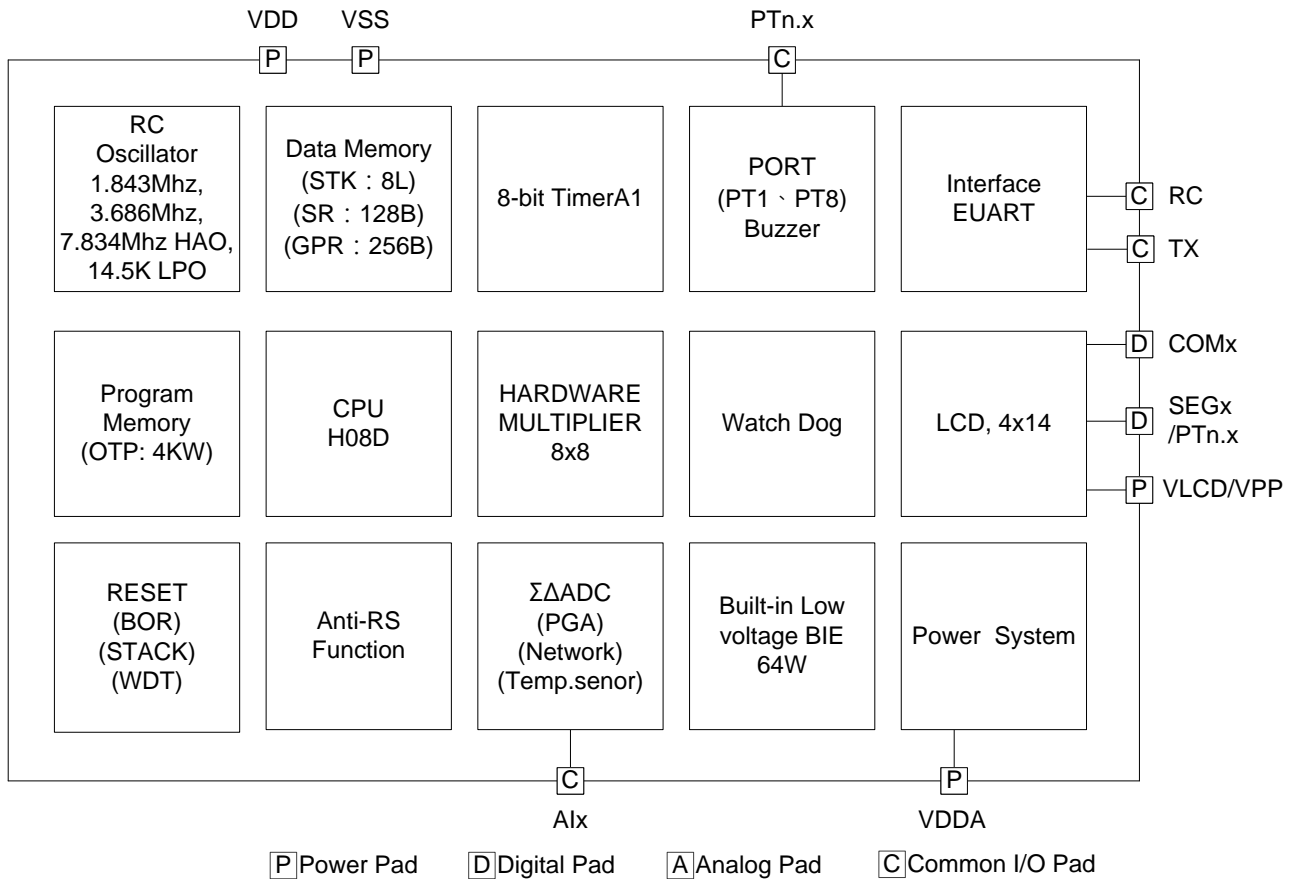


Figure 4-1 Internal Block Diagram

4.2. Related Description and Supporting Document

File Name	Description
DS-HY17P51	HY17P51 Datasheet
UG-HY17S58	HY17S58 chip User's Manual
APD-CORE002	H08A, H08C, H08D Instruction Set User's Manual
APD-HY17PIDE001	HY17P Series development tool software User's Manual
APD-HY17PIDE002	HY17P Series development tool hardware User's Manual
APD-HYIDE016	H08 C IDE software User's Manual
APD-HY17PIDE003	HY17P4x/5x Series Peripheral Driver C Library User's Manual
APD-HY17PIDE004	HY17P Series HexLoader User's Manual
APD-HYIDE014	HY10000-WK08D Integrated Writer software User's Manual
APD-HYIDE013	HY10000-WK08D Integrated Writer hardware User's Manual

4.3. Clock System

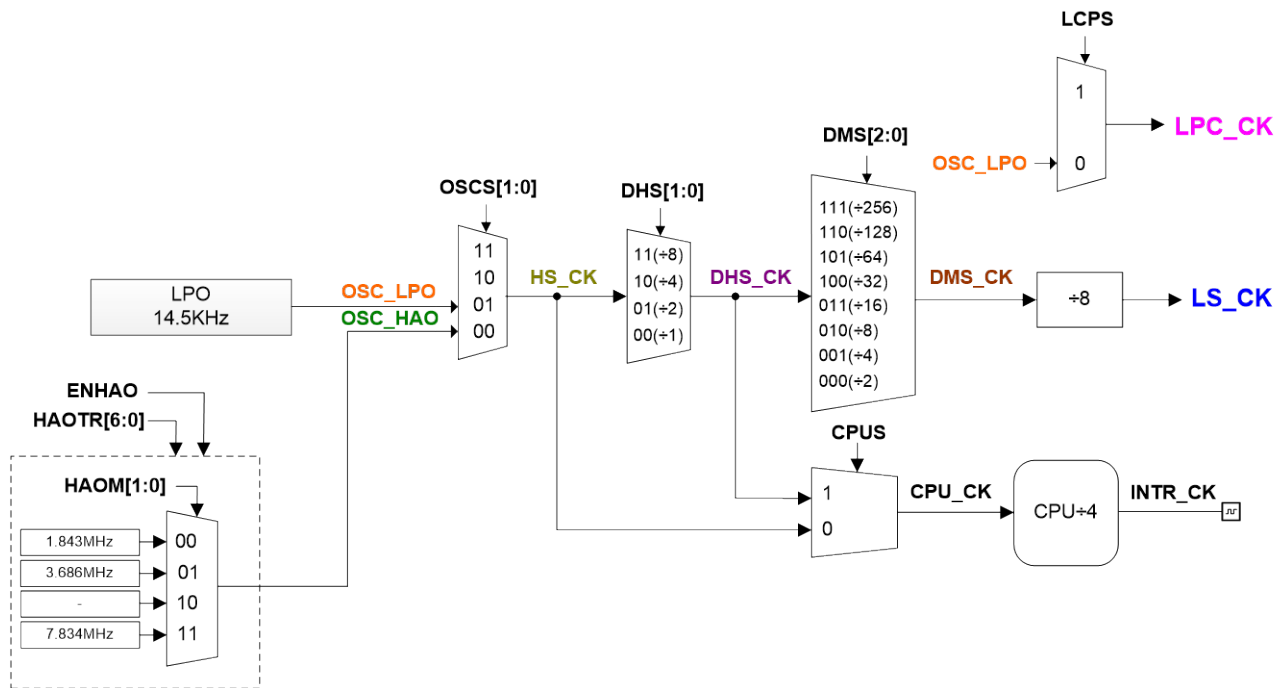


Figure 4-2 Clock System block diagram (1)

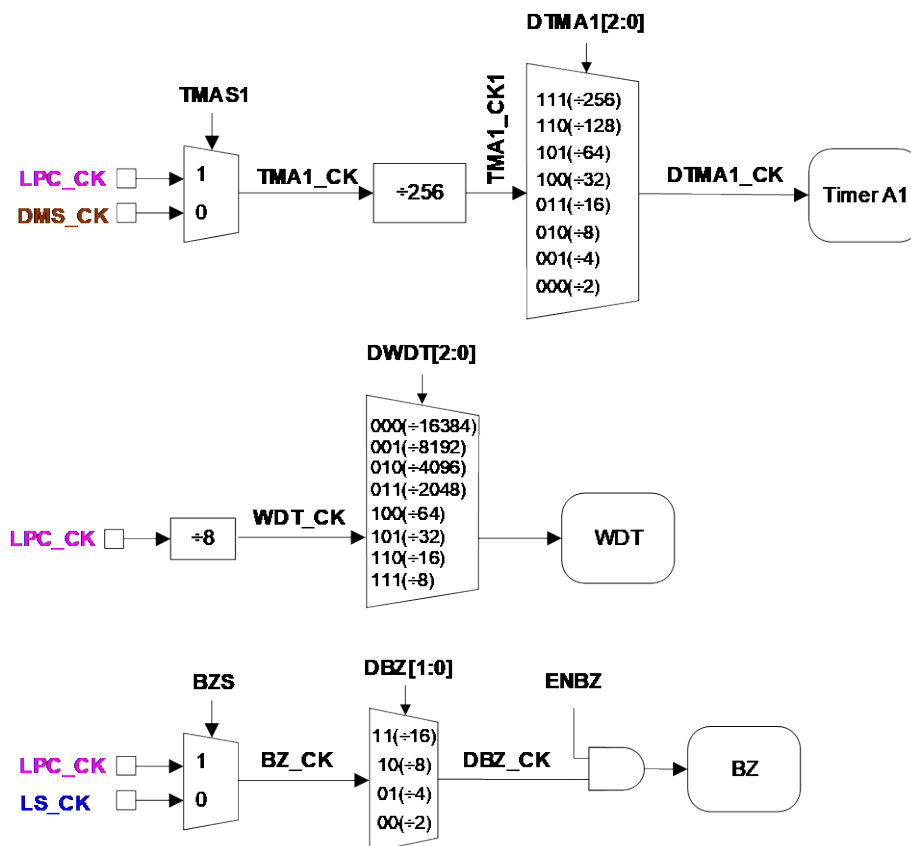


Figure 4-3 Clock System block diagram (2)

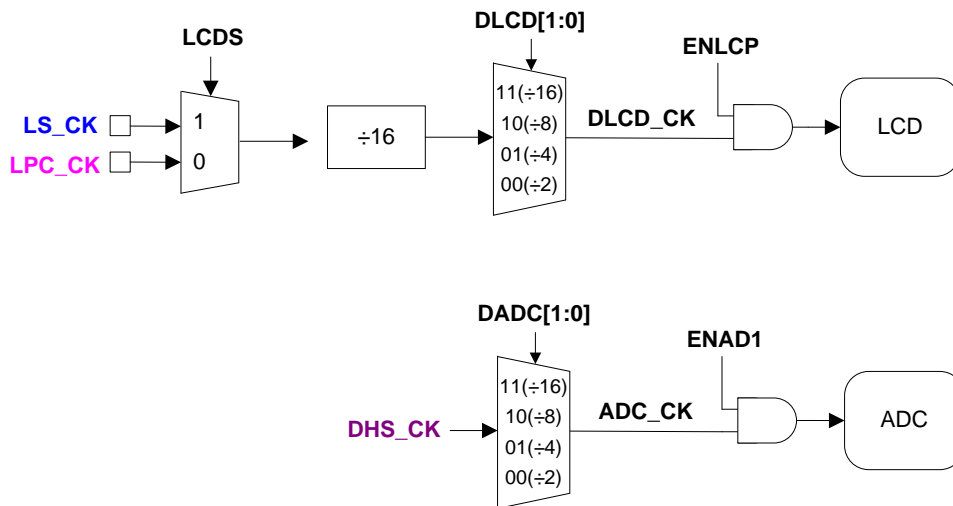


Figure 4-4 Clock System block diagram (3)

4.4. Low Voltage Detect(LVD)

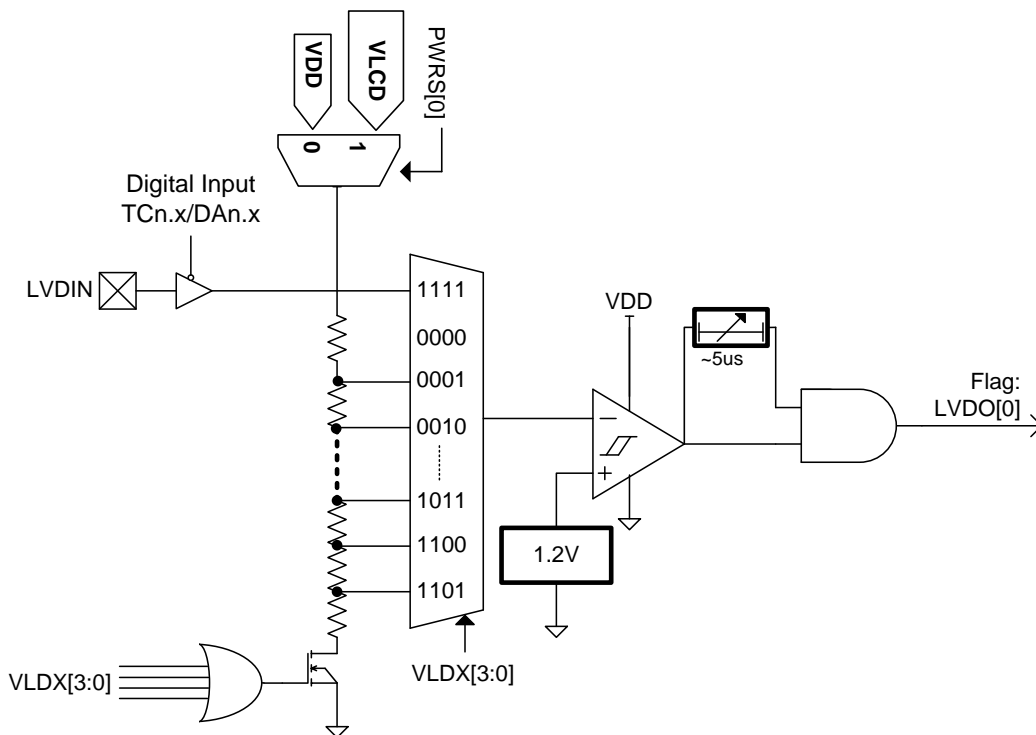


Figure 4-5 Low Voltage Detect block diagram

4.5. Reset

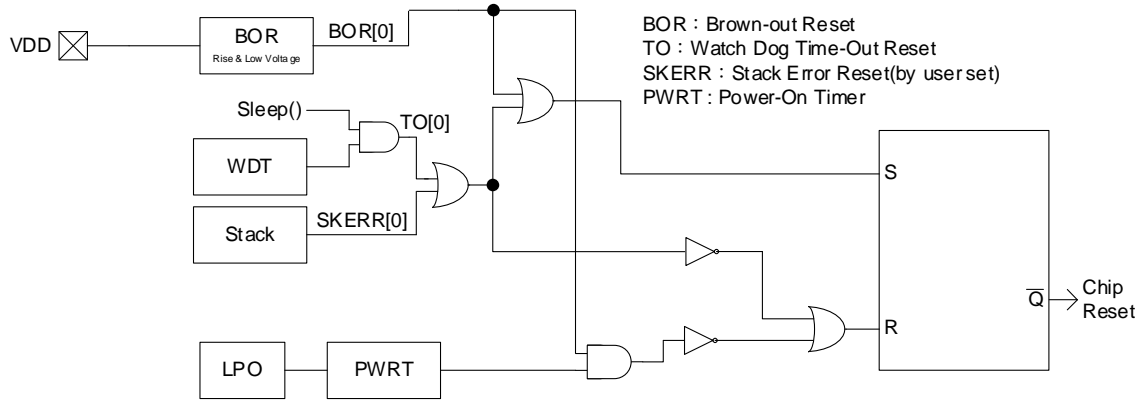


Figure 4-6 Reset block diagram

4.6. Power System

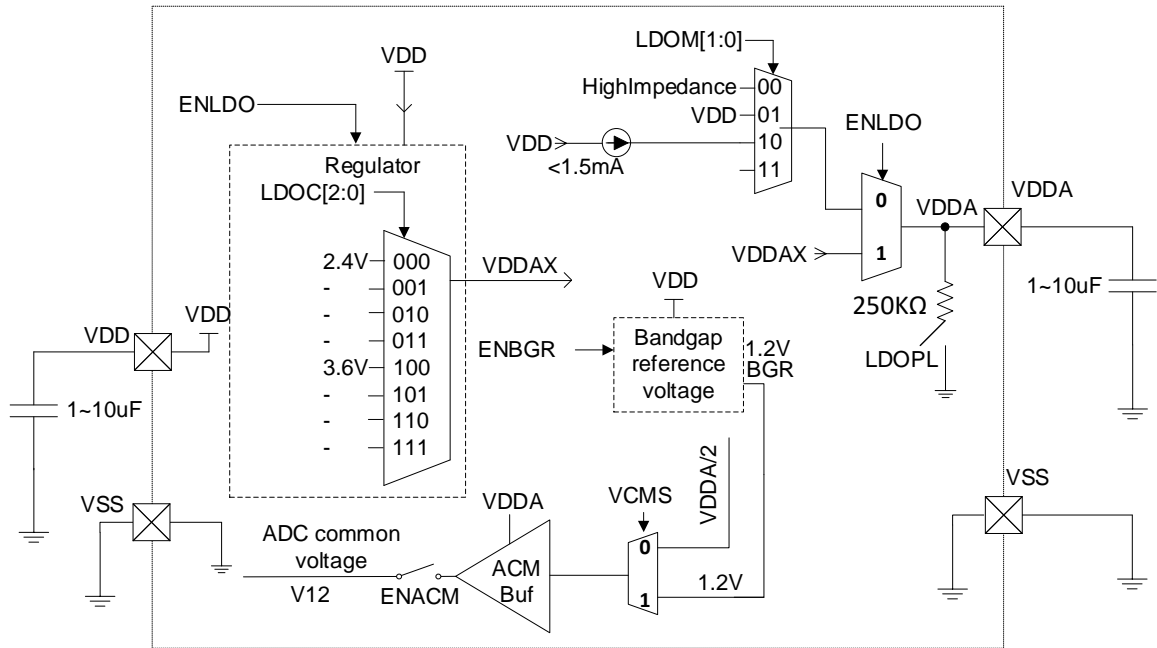


Figure 4-7 Power System block diagram

4.7. $\Sigma\Delta$ ADC Network

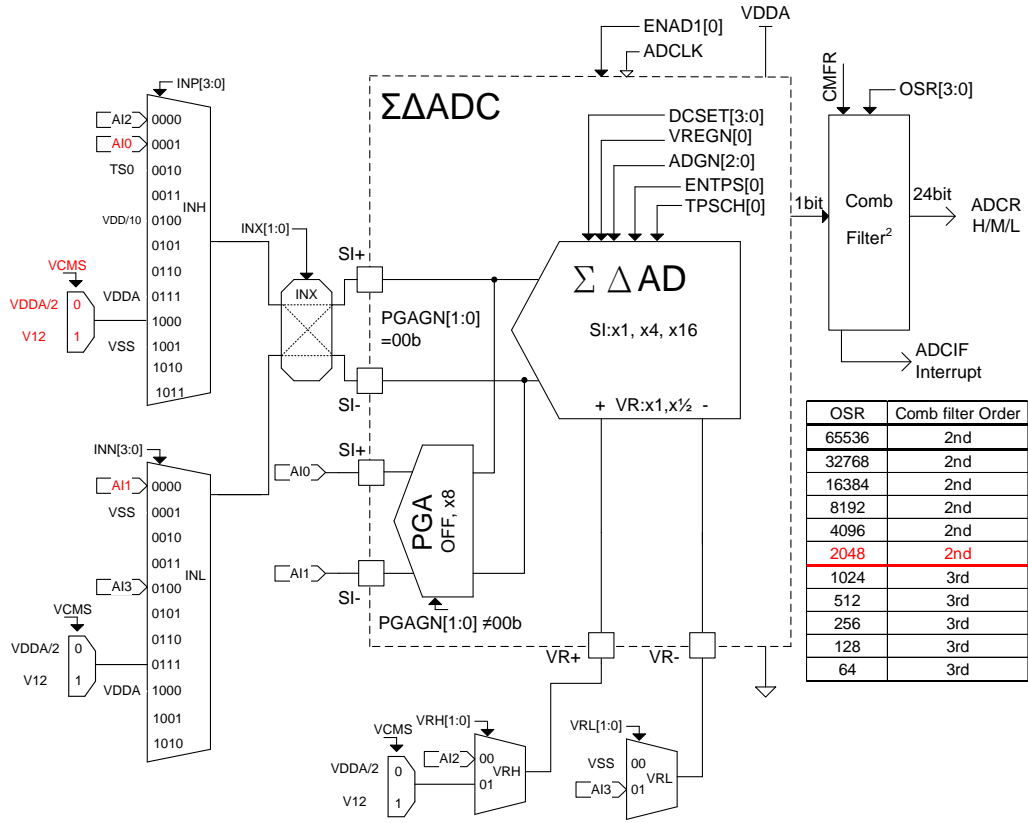


Figure 4-8 $\Sigma\Delta$ ADC Network

4.8. GPIO PT1

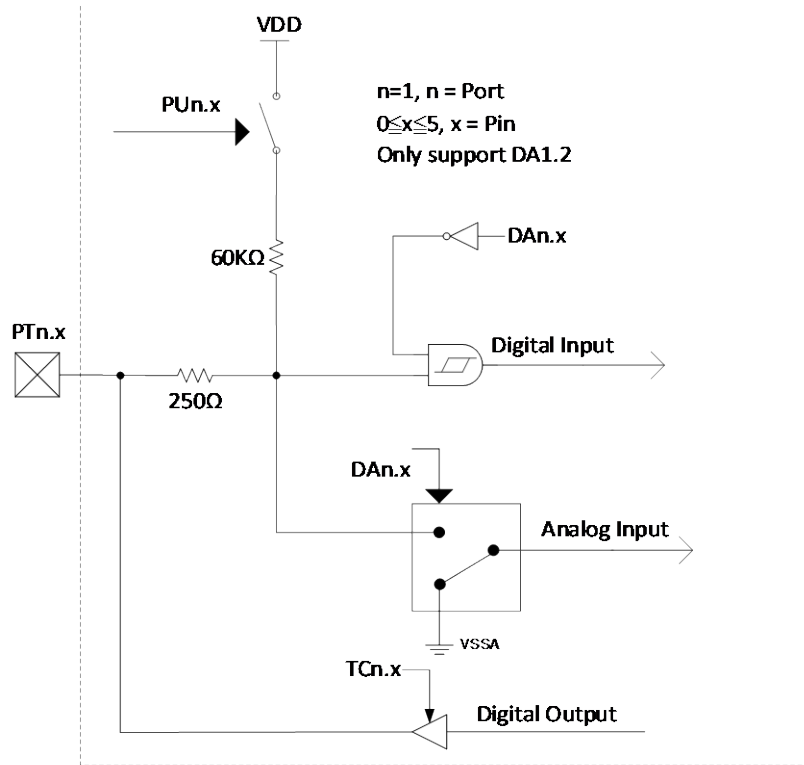


Figure 4-9 GPIO PT1 block diagram

4.9. GPIO PT8/SEG14~SEG15

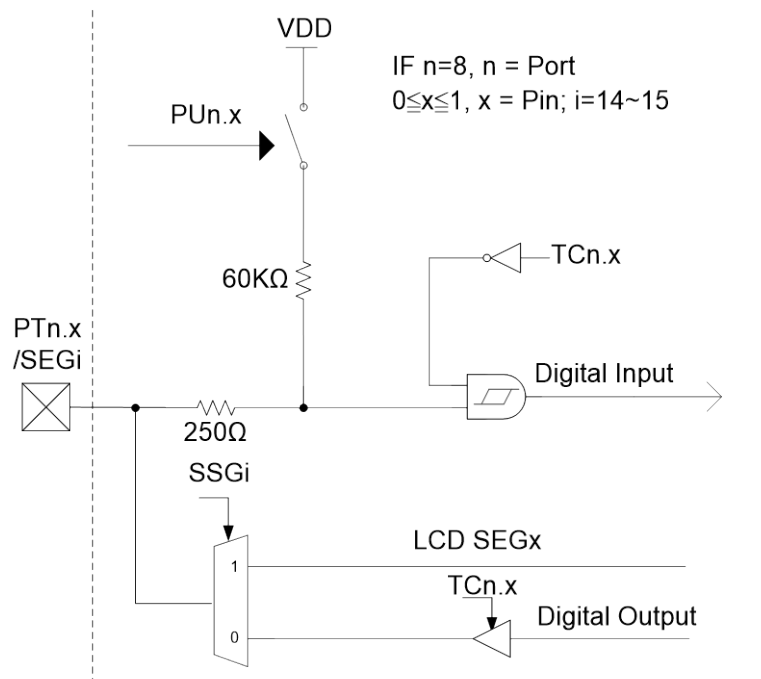


Figure 4-10 GPIO PT8/SEG14~SEG15 block diagram

4.10. Watch Dog

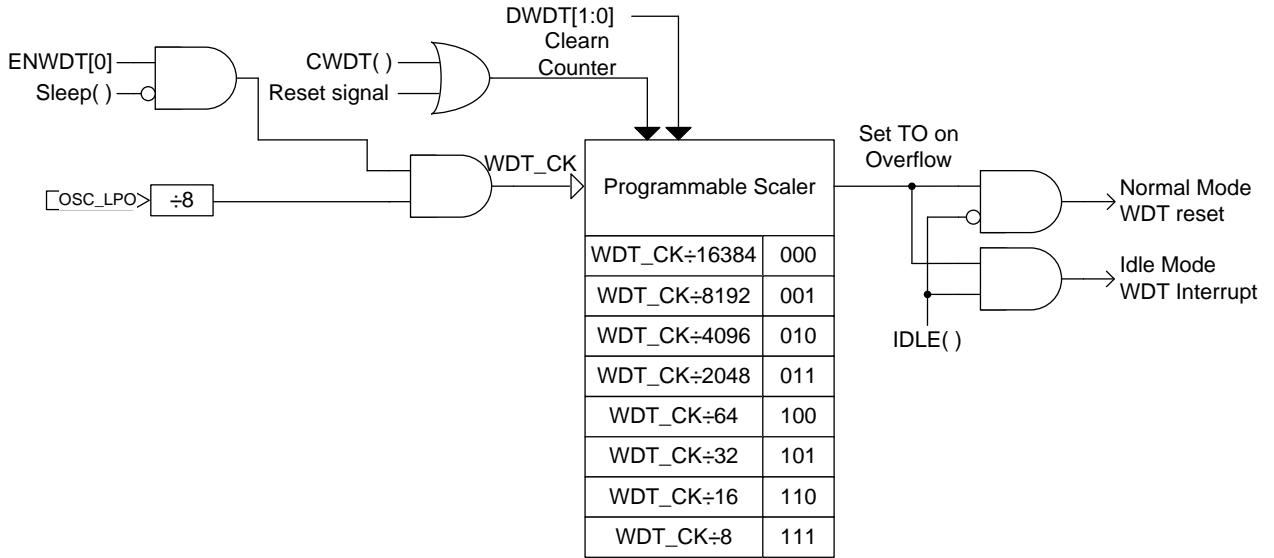


Figure 4-11 Watch Dog block diagram

4.11. 8-bit Timer A1

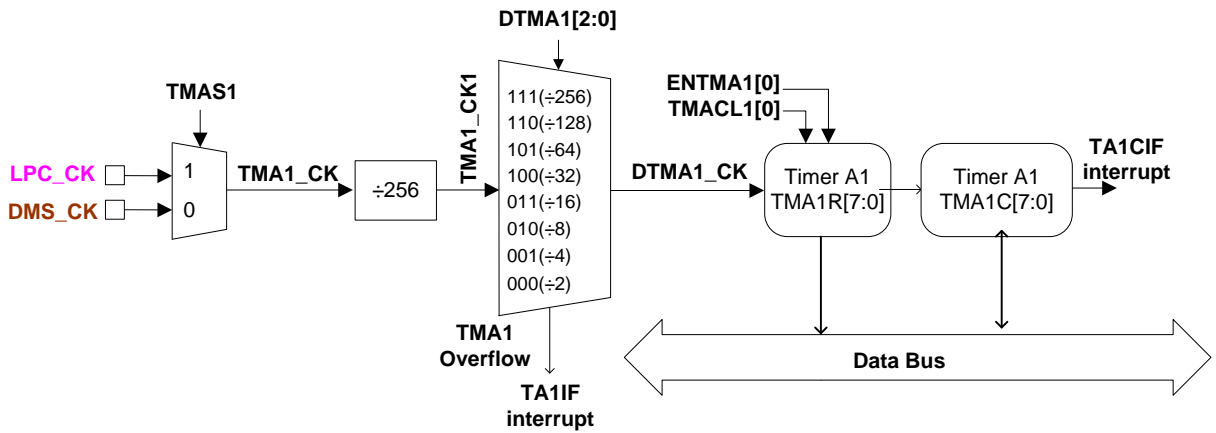


Figure 4-12 8-bit Timer A1 block diagram

4.12. LCD

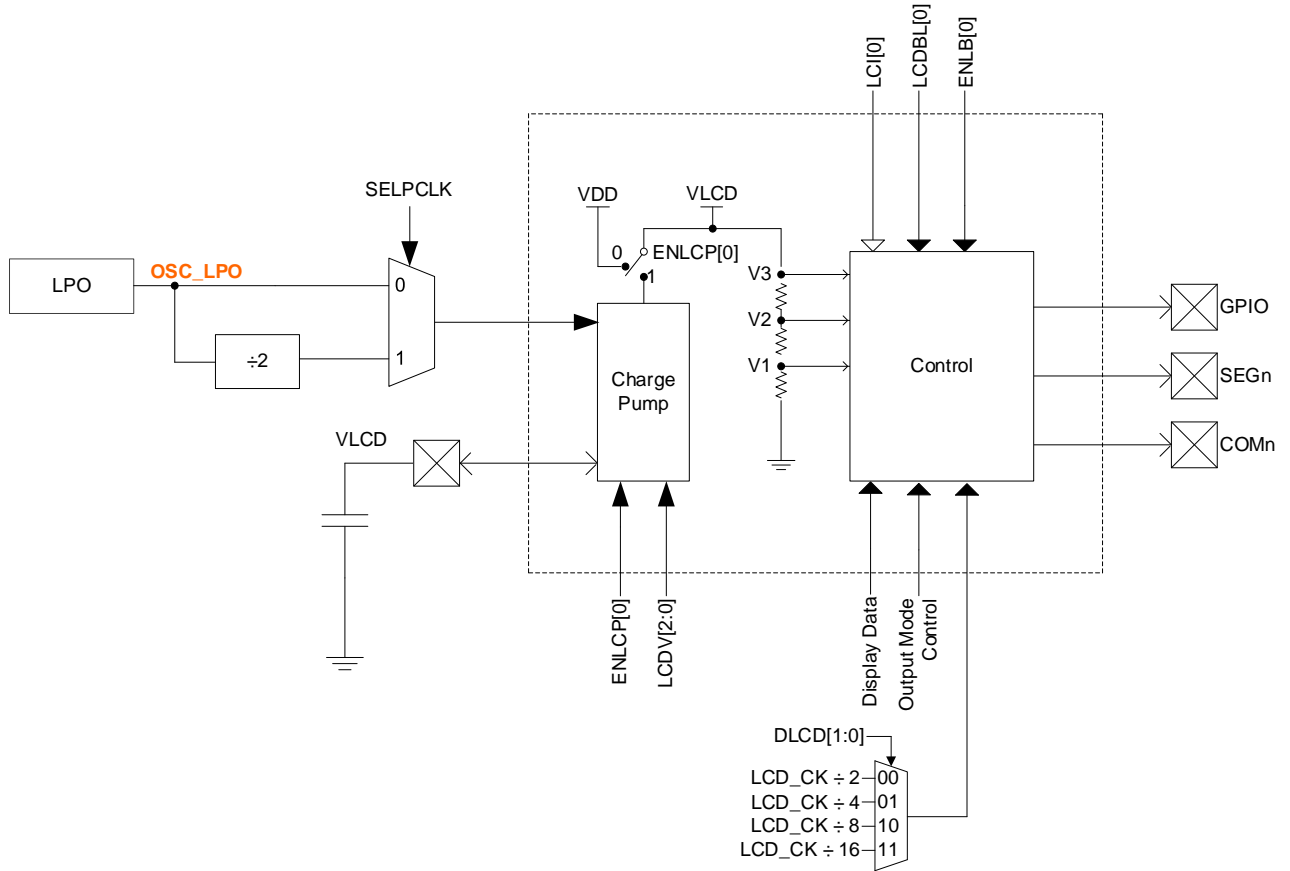


Figure 4-13 LCD block diagram

4.13. EUART

EUART TRANSMIT BLOCK DIAGRAM

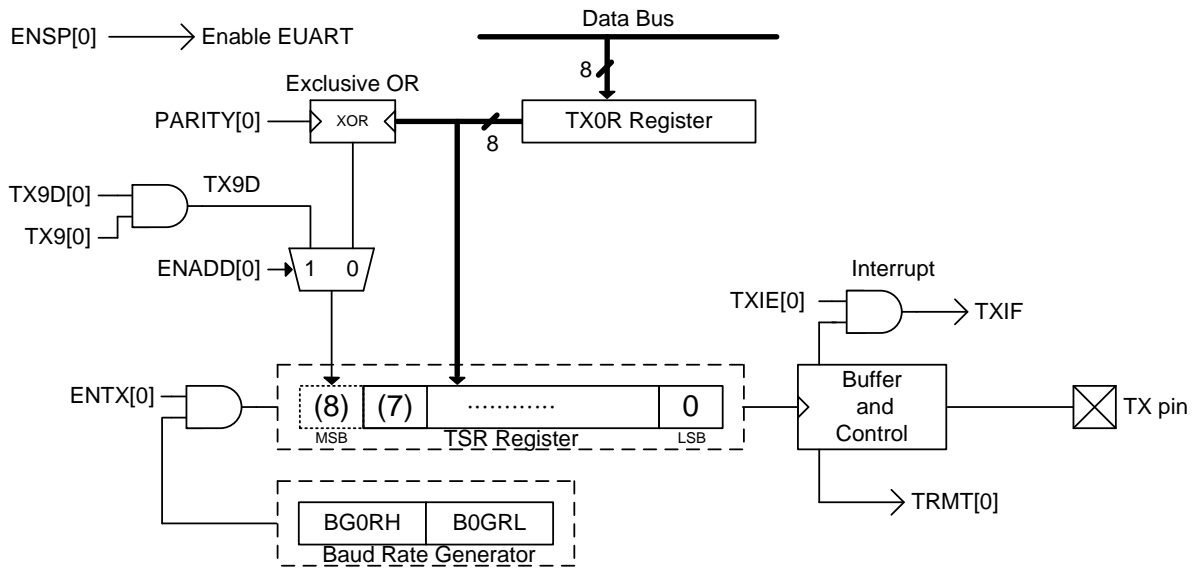
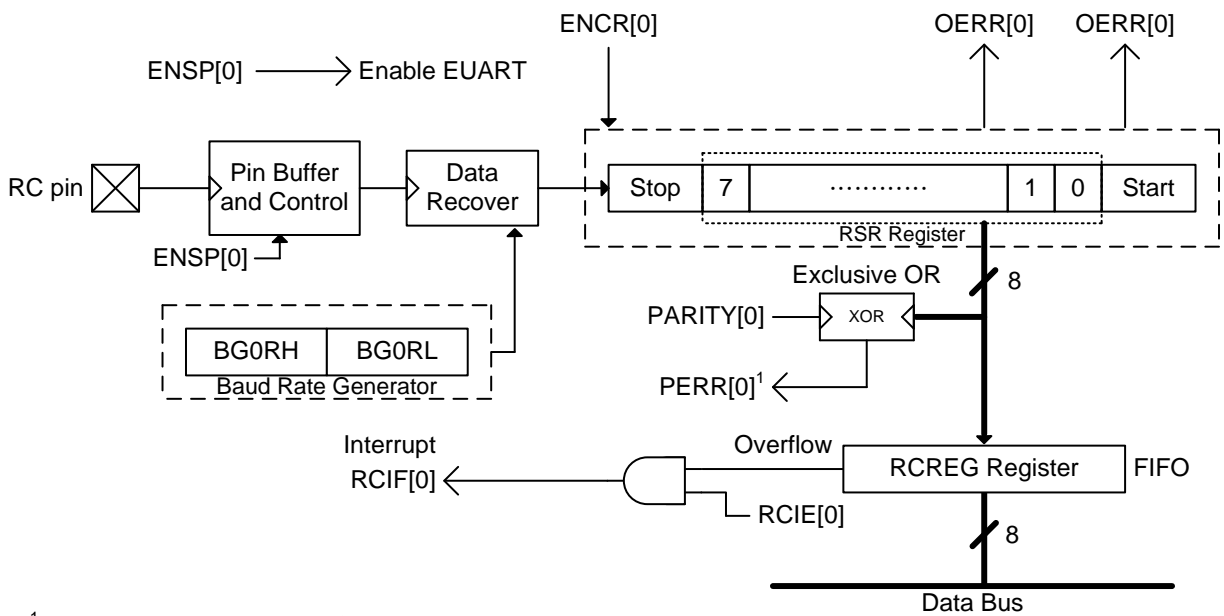


Figure 4-14 EUART transmit block diagram

EUART 8-BITS RECEIVE BLOCK DIAGRAM



¹Don't care PERR[0] state of 8-bits receive mode

Figure 4-15 EUART 8-bits receive block diagram

5. Register list

"-"no use, "*"read/write, "w"write, "r"read, "r0"only read 0, "r1"only read 1, "w0"only write 0, "w1"only write 1
 "\$"for event status, "u"unimplemented bit, "x"unknown, "u"unchanged, "d"depends on condition

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	ARST	IRST	R/W
000h	INDF0	Contents of FSR0 to address data memoryvalue of FSR0 not changed								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
001h	POINC0	Contents of FSR0 to address data memoryvalue of FSR0 post-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
002h	PODEC0	Contents of FSR0 to address data memoryvalue of FSR0 post-decremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
003h	PRINC0	Contents of FSR0 to address data memoryvalue of FSR0 pre-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
004h	PLUSW0	Contents of FSR0 to address data memoryvalue of FSR0 offset by W								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
005h	INDF1	Contents of FSR1 to address data memoryvalue of FSR1 not changed								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
006h	POINC1	Contents of FSR1 to address data memoryvalue of FSR1 post-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
007h	PODEC1	Contents of FSR1 to address data memoryvalue of FSR1 post-decremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
008h	PRINC1	Contents of FSR1 to address data memoryvalue of FSR1 pre-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
009h	PLUSW1	Contents of FSR1 to address data memoryvalue of FSR1 offset by W								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Ah	INDF2	Contents of FSR2 to address data memoryvalue of FSR2 not changed								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Bh	POINC2	Contents of FSR2 to address data memoryvalue of FSR2 post-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Ch	PODEC2	Contents of FSR2 to address data memoryvalue of FSR2 post-decremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Dh	PRINC2	Contents of FSR2 to address data memoryvalue of FSR2 pre-incremented								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Eh	PLUSW2	Contents of FSR2 to address data memoryvalue of FSR2 offset by W								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
00Fh	FSROH	-	-	-	-	-	-	-	FSR0[8]XU	-1-1-1-1-1-1-1-1
010h	FSR0L	Indirect Data Memory Address Pointer 0 Low Byte,FSR0[7:0]								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
011h	FSR1H	-	-	-	-	-	-	-	FSR1[8]XU	-1-1-1-1-1-1-1-1
012h	FSR1L	Indirect Data Memory Address Pointer 0 Low Byte,FSR1[7:0]								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
016h	TOSH	-	-	-	-	TOS[11:8]			xxxxuuuu	-1-1-1-1-1-1-1-1
017h	TOSL	Top-of-Stack Low Byte (TOS<7:0>)								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
018h	SKCN	SKFL	SKUN	SKOV	-	SKPRT[3:0]				000.0000	u\$\$.\$\$\$	rw 0,rw 0,rw 0,-
01Ah	PCLATH	-	-	-	-	PC[11:8]			00000000	-1-1-1-1-1-1-1-1
01Bh	PCLATL	PC Low Byte for PC<7:0>								0000 0000	0000 0000	***** 1 1 1 1 1 1
01Dh	TBLPTRH	-	-	-	-	TBLPTR11:8]			xxxxuuuu	-1-1-1-1-1-1-1-1
01Eh	TBLPTL	Program Memory Table Pointer Low Byte (TBLPTR<7:0>)								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
01Fh	TBLDH	Program Memory Table Latch High Byte								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
020h	TBLDL	Program Memory Table Latch Low Byte								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
021h	PRODH	Product Register of Multiply High Byte								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
022h	PRODL	Product Register of Multiply Low Byte								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
023h	INTE0	GIE	TA1CIE	ADIE	WDTIE	-	-	E1IE	E0IE	0000 0000	0uuu uuuu	***** 1 1 1 1 1 1
024h	INTE1	TA1IE	-	TXIE	RCIE	-	-	-	-	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1
026h	INTF0	-	TA1CIF	ADIF	WDTIF	-	-	E1IF	E0IF	.000 0000	.uuu uuuu	***** 1 1 1 1 1 1
027h	INTF1	TA1IF	-	TXIF	RCIF	-	-	-	-	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1
029h	WREG	Working Register								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
02Ah	BSRCN	-	-	-	-	-	-	-	BSR[0]XU	-1-1-1-1-1-1-1-1
02Bh	MSTAT	-	-	-	C	DC	N	OV	Z	...x xxxx	...u uuuu	-1-1-1-1-1-1-1-1
02Ch	PSTAT	BOR	PD	TO	IDL	RST	SKERR	-	-	\$000 \$0..	uu\$u u\$..	rw0,rw0,rw0,rw0,rw0,rw0,-
02Eh	BIECN	1	-	-	ENBVD	VPPHV	ENBCP	BIEWR	BIERD	1.00 \$000	1.00 \$uuu	r1-1-1-1-1-1-1-1
02Fh	BIEARH	-	-	1	1	1	1	1	1	0.xx xxxx	u.uu uuuu	-1-1-1-1-1-1-1-1
030h	BIEARL	BIE Address Register as BIEAL[5:0]								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
031h	BIEDRH	BIE High Byte Data Register								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
032h	BIEDRL	BIE Low Byte Data Register								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1
033h	PWRCN	ENBGR	LDOC[2:0]		LDOM[1:0]		ENLDO	CSFON		1000 0000	uuuu uu0u	***** 1 1 1 1 1 1
034h	OSCCN0	-	OSCS[0]	DHS[1:0]		DMS[2:0]		CUPS		0000 0000	uuuu uuuu	***** 1 1 1 1 1 1
035h	OSCCN1	CCOPT	-	DADC[1:0]		-	-	-	LCDS	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1
036h	OSCCN2	DLCD[1:0]		-	-	-	HAOM[1:0]	ENHAO		0000 0011	uuuu uu11	***** 1 1 1 1 1 1
037h	CSFCN0	SKRST	HAOTR[6:0]							.1..	-1-1-1-1-1-1-1-1
038h	CSFCN1	ENSDRV	-	-	-	-	-	-	-	uuuu uuuu	***** 1 1 1 1 1 1
039h	WDTCN	ENBZ	BZS	BZ[1:0]		ENWDT	DWDWT[2:0]			0000 0000	uuuu \$000	-1-1-1-1-1-1-1-1
03Ah	AD1H	ADC1 conversion high byte data register								..00 0000	..uu uuuu	-1-1-1-1-1-1-1-1
03Bh	AD1M	ADC1 conversion middle byte data register								0000 0000	uuuu uuuu	***** 1 1 1 1 1 1
03Ch	AD1L	ADC1 conversion low byte data register								0000 0000	uuuu uuuu	***** 1 1 1 1 1 1

Table 5-1 Data memory list (1)

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“-”no use,“r”read/write,“w”write,“r”read,“r0”onlyread 0,“r1”onlyread 1,“w0”onlywrite 0,“w1”onlywrite 1
“\$”for event status,“.”unimplemented bit,“x”unknown,“u”unchanged,“d”depends on condition

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	ARST	IRST	R/W
03Dh	AD1CN0	ENAD1	-	OSR[3:0]			CMFR			0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
03Eh	AD1CN1	INIS1	-	VREGN	PGAGN[1:0]		ADGN[2:0]			xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
03Fh	AD1CN2	-	-	-	DCSET[3:0]			xxxx xxxx			uuuu uuuu	***** 1 1 1 1 1 1 1
040h	AD1CN3	INP[3:0]			INN[3:0]			xxxx xxxx			uuuu uuuu	***** 1 1 1 1 1 1 1
041h	AD1CN4	VRH[1:0]		VRL[1:0]		INX[1:0]		VRIS	INIS	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
042h	AD1CN5	ENACM	-	VCMS	LDOPL	-	-	ENTPS	TPSCH	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
043h	LVDCN	-	-	PWRS	LVDS[3:0]			LVDO		0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
044h	TMA1CN	ENTMA1	TMACL1	TMAS1	DTMA1[2:0]			-		0000 0000	u0uu uuuu	*,\$,rw 1,***** 1 1 1 1 1 1 1
045h	TMA1R	TMA1 counter Register								0000 0000	uuuu uuuu	rw0,rw0,rw0,rw0 rw0,rw0,rw0,rw0
046h	TMA1C	TMA1C counter Register								0000 0000	uuuu uuuu	rw0,rw0,rw0,rw0 rw0,rw0,rw0,rw0
047h	PT1	-	-	PT1.5	PT1.4	PT1.3	PT1.2	PT1.1	PT1.0	xxxx xxxx	xxxx xxxx	***** 1 1 1 1 1 1 1
048h	TRISC1	-	-	TC1.5	TC1.4	TC1.3	TC1.2	TC1.1	TC1.0	xx00 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
049h	PT1DA	-	-	-	-	-	DA1.2	-	-	xxxx x0xx	uuuu uuuu	***** 1 1 1 1 1 1 1
04Ah	PT1PU	-	-	PU1.5	PU1.4	PU1.3	PU1.2	PU1.1	PU1.0	xx11 1111	uuuu uuuu	***** 1 1 1 1 1 1 1
04Bh	PT1M1	-	-	-	-	INTEG1[1:0]		INTEG0[1:0]		0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
04Ch	PT8	-	-	-	-	-	-	PT8.1	PT8.0	xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
04Dh	TRISC8	-	-	-	-	-	-	TC8.1	TC8.0	xxxx xx00	uuuu uuuu	***** 1 1 1 1 1 1 1
04Eh	PT8DA	-	-	-	-	-	-	DA8.1	DA8.0	xxxx xx00	uuuu uuuu	***** 1 1 1 1 1 1 1
04Fh	PT8PU	-	-	-	-	-	-	P8.1	P8.0	xxxx xx11	uuuu uuuu	***** 1 1 1 1 1 1 1
050h	UROCN	ENSP	ENTX	TX9	TX9D	PARITY	-	-	WUE	0000 0..0	uuuu u..u	***** 1 1 1 1 1 1 1
051h	UR0STA	-	RC9D	PERR	FERR	OERR	RCIDL	TRMT	ABDOVF	.000 0010	.uuu uuuu	-,r,r,r,r,r,r,r,rw 0
052h	BA0CN	-	-	-	-	ENCR	RC9	ENADD	ENABD 0000 uuuu	-,r,r,r,r,r,r,r,r
053h	BG0RH	-	-	-	Baud Rate Generator Register High Byte					...x xxxx	...u uuuu	-,r,r,r,r,r,r,r,r
054h	BG0RL	Baud Rate Generator Register Low Byte								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
055h	TX0R	UART Transmit Register								xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
056h	RC0REG	UART Receive Register								xxxx xxxx	uuuu uuuu	r,r,r,r,r,r,r,r
057h	LCDCN1	ENLCP	LCDV[2:0]			ENLB	SELPCLK	-	-	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
058h	LCDCN2	-	-	-	-	-	-	LCDBL	LCI00uu	***** 1 1 1 1 1 1 1
059h	LCDCN3	SCM3[1:0]		SCM2[1:0]		SCM1[1:0]		SCM0[1:0]		1111 1111	uuuu uuuu	***** 1 1 1 1 1 1 1
05Ah	LCDCN4	-	-	-	-	-	-	SSG15	SSG14	0000 0000	uuuu uuuu	***** 1 1 1 1 1 1 1
05Bh	LCD0	LCD SEG3[4:7] data				LCD SEG2[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
05Ch	LCD1	LCD SEG5[4:7] data				LCD SEG4[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
05Dh	LCD2	LCD SEG7[4:7] data				LCD SEG6[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
05Eh	LCD3	LCD SEG9[4:7] data				LCD SEG8[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
05Fh	LCD4	LCD SEG11[4:7] data				LCD SEG10[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
060h	LCD5	LCD SEG13[4:7] data				LCD SEG12[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
061h	LCD6	LCD SEG15[4:7] data				LCD SEG14[3:0] data				xxxx xxxx	uuuu uuuu	***** 1 1 1 1 1 1 1
080h ~ 17Fh	SRAM as 256Byte								uuuu uuuu	uuuu uuuu	***** 1 1 1 1 1 1 1	

Table 5-2 Data memory list (2)

6. Electrical Characteristics

Absolute Maximum Ratings :

Absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Voltage applied at VDD to VSS	-0.2 V to 6.0 V
Voltage applied to any pin	-0.2 V to VDD + 0.3 V
Voltage applied to VLCD/VPP pin	-0.2 V to 8.0 V
Diode current at any device terminal	±2 mA
Storage temperature, Tstg: (unprogrammed device)	-55°C to 125°C
(programmed device)	-40°C to 85°C
Total power dissipation.....	0.5w
Maximum output current sink by any I/O pin.....	20mA

6.1. Recommended operating conditions

A = -40°C ~ 85°C, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
VDD	Supply Voltage	All digital peripherals and CPU	2.0		5.5	V
VDDA	Supply Voltage	Analog peripherals	2.4		5.0	
VSS	Supply Voltage		0		0	

6.2. Internal RC Oscillator

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
HAO	High Speed Oscillator frequency	ENHAO[0]=1, HAOM[1:0]=00	-20%	1.843	+20%	MHz
		ENHAO[0]=1, HAOM[1:0]=01	-20%	3.686	+20%	MHz
		ENHAO[0]=1, HAOM[1:0]=11	-20%	7.834	+20%	MHz
		After Frequency Trim by Writer	-2%		+2%	MHz
LPO	Low Power Oscillator frequency	VDD supply voltage be enable LPO	-20%	14.5	+20%	KHz

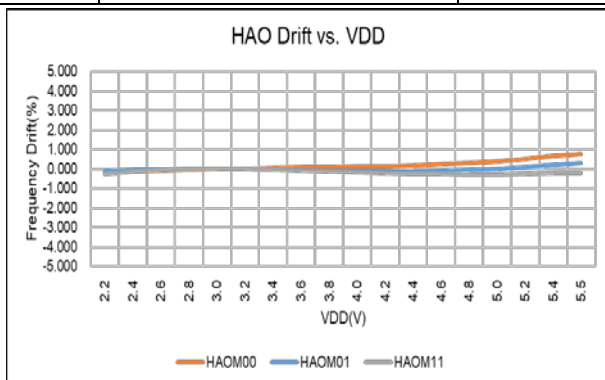


Figure 6.2-1 HAO vs. VDD

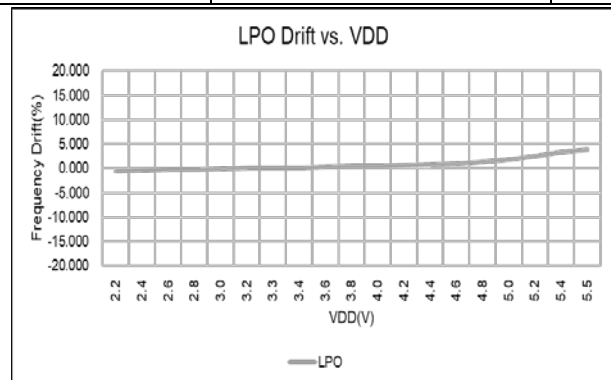


Figure 6.2-2 LPO vs. VDD

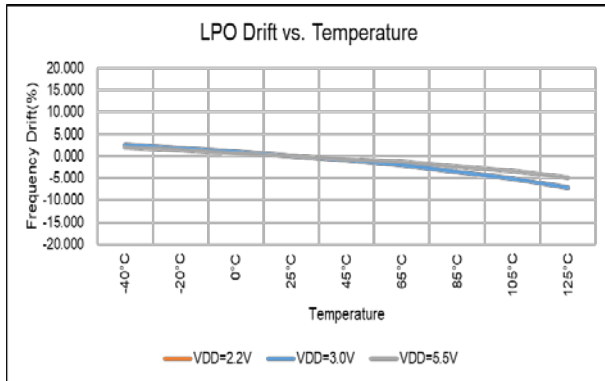


Figure 6.2-3 LPO vs. Temperature

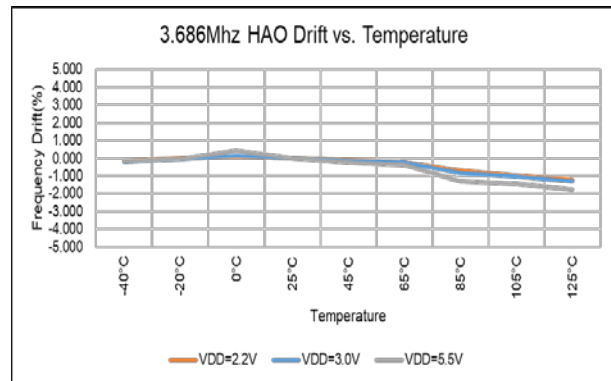


Figure 6.2-4 HAO(3.686MHz) vs. Temperature

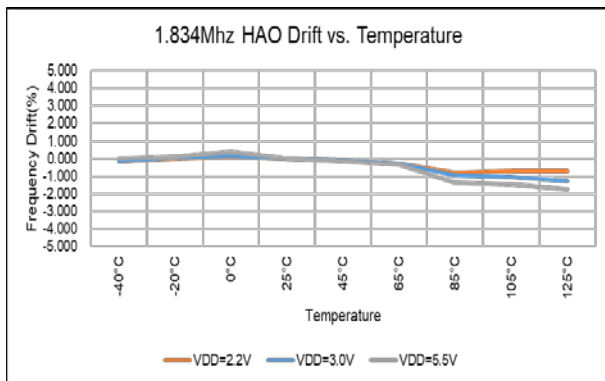


Figure 6.2-4 HAO(1.843MHz) vs. Temperature

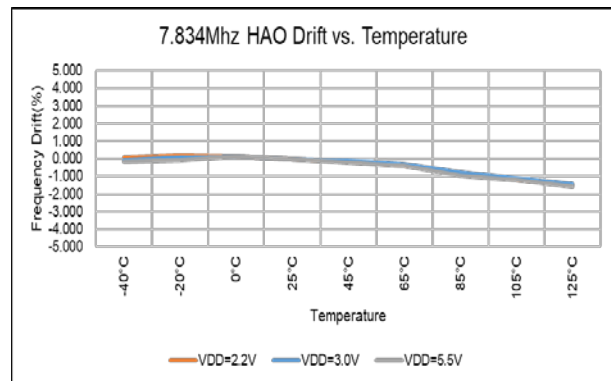


Figure 6.2-6 HAO(7.834MHz) vs. Temperature

6.3. Supply current into VDD excluding peripherals current

TA = 25°C, VDD = 3.0V, OSC_LPO = 14.5KHz, , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	unit
I _{AM2}	Active mode 2	OSC_CY = off, OSC_HAO = 3.686MHz, CPU_CK = 3.686MHz		320	650	uA
I _{AM5}	Active mode 5	OSC_CY = off, OSC_HAO = 3.686MHz, CPU_CK = 3.686MHz/2		250	500	uA
I _{LP1}	Low Power 1	OSC_CY = off, OSC_HAO=off, CPU_CK = LPO		2	5	uA
I _{LP2}	Low Power 2	OSC_CY = off, OSC_HAO=off, CPU_CK = LPO, Idle state		1.1	2.5	uA
I _{LP3}	Low Power 3	OSC_CY = off, OSC_HAO=off, CPU_CK = off, Sleep state		0.4	1.0	uA

OSC_HAO : Internal High Accuracy Oscillator frequency.

CPU_CK : CPU core work frequency.

TA = 25°C, VDD = 5.5V, OSC_LPO = 14.5KHz, , unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	unit
I _{AM2}	Active mode 2	OSC_CY = off, OSC_HAO = 3.686MHz, CPU_CK = 3.686MHz		720	1200	uA
I _{AM5}	Active mode 5	OSC_CY = off, OSC_HAO = 3.686MHz, CPU_CK = 3.686MHz/2		600	900	uA
I _{LP1}	Low Power 1	OSC_CY = off, OSC_HAO=off, CPU_CK = LPO		4	10	uA
I _{LP2}	Low Power 2	OSC_CY = off, OSC_HAO=off, CPU_CK = LPO, Idle state		2.5	5	uA
I _{LP3}	Low Power 3	OSC_CY = off, OSC_HAO=off, CPU_CK = off, Sleep state		0.4	2	uA

OSC_HAO : Internal High Accuracy Oscillator frequency.

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CPU_CK : CPU core work frequency.

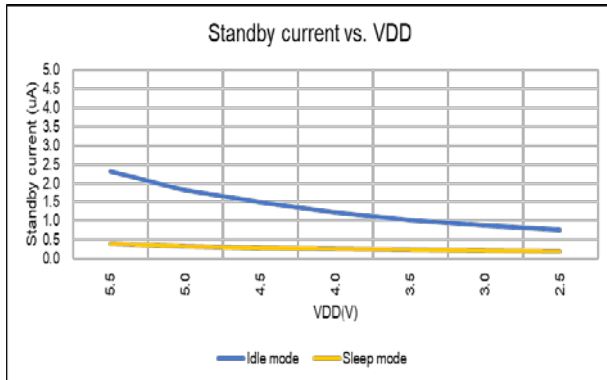


Figure 6.3-1 Standby current vs. VDD

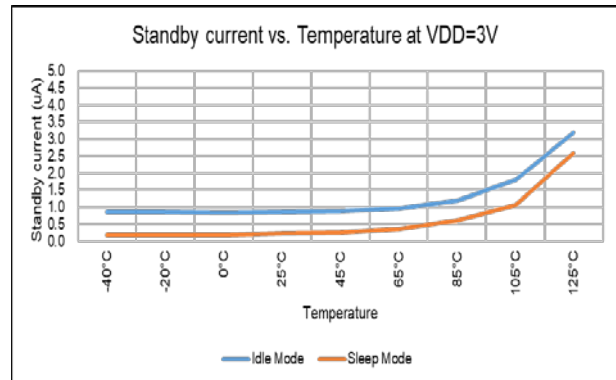


Figure 6.3-2 Standby current vs. Temperature VDD=3V

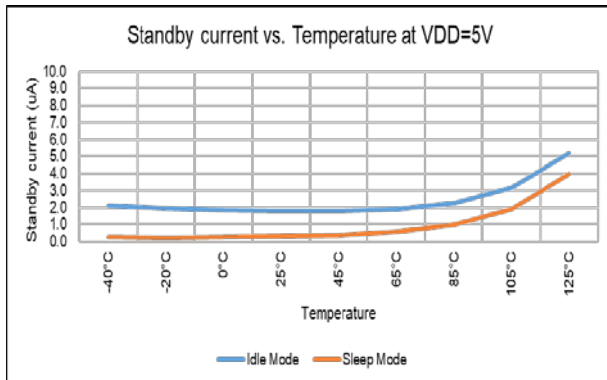


Figure 6.3-3 Standby current vs. Temperature at VDD=5V

6.4. Port 1 & 8

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Input voltage and Schmitt trigger and leakage current and timing						
V _{IH}	High-Level input voltage				0.7*VDD	V
V _{IL}	Low-Level input voltage		0.3*VDD			
V _{hys}	Input Voltage hysteresis(V _{IH} - V _{IL})			0.3*VDD		V
I _{LKG}	Leakage Current				0.1	uA
R _{PU}	Port pull high resistance(PT1、PT2)			60		kΩ
	Port pull high resistance(PT8)			60		kΩ
Output voltage and current and frequency						
V _{OH}	High-level output voltage	VDD<4V, I _{OH} =3mA,	VDD -0.3			V
		VDD>=4V, I _{OH} =5mA,	VDD -0.3			
V _{OL}	Low-level output voltage	VDD<4V, I _{OL} =-3mA			VSS +0.3	
		VDD>=4V, I _{OL} =-5mA			VSS +0.3	

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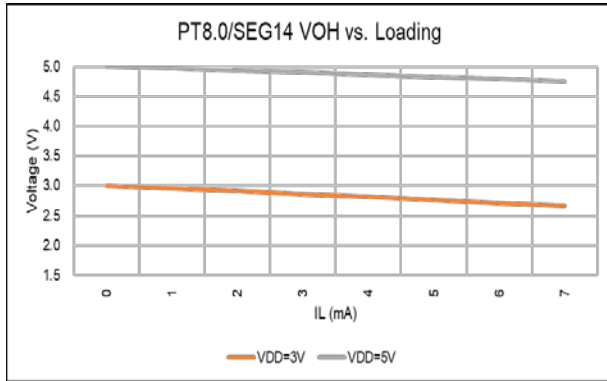


Figure 6.4-1 PT8.0/SEG14 VOH vs. Loading

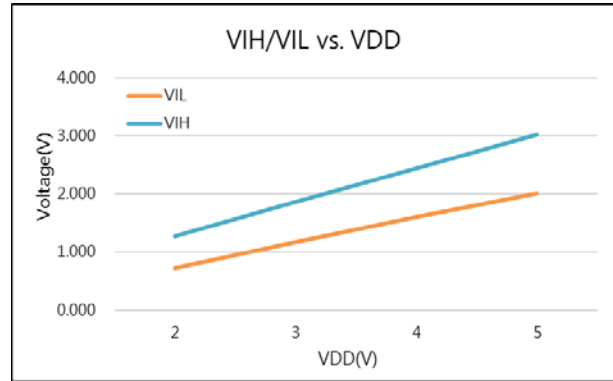


Figure 6.4-2 V_{IH}/V_{IL} vs. VDD

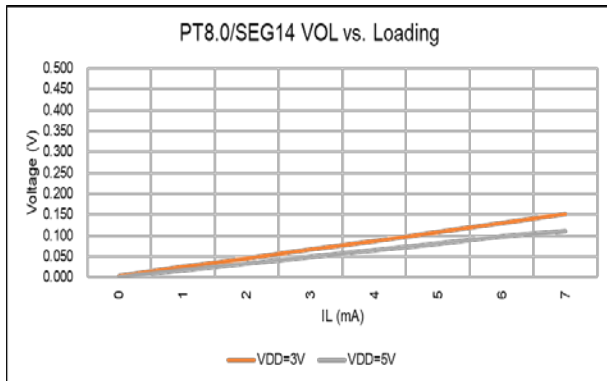


Figure 6.4-3 PT8.0/SEG14 VOL vs. Loading

6.5. Port1.4~Port1.5

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Input voltage and Schmitt trigger and leakage current and timing						
V_{IH}	High-Level input voltage				0.7*VDD	V
V_{IL}	Low-Level input voltage		0.3*VDD			
V_{hys}	Input Voltage hysteresis($V_{IH} - V_{IL}$)			0.3*VDD		V
I_{LKG}	Leakage Current				0.1	μ A
R_{PU}	Port pull high resistance			60		k Ω
Output voltage and current and frequency						
V_{OH}	High-level output voltage	VDD=3V, I_{OH} =10mA,	VDD -0.4			V
		VDD=5V, I_{OH} =15mA,	VDD -0.4			
V_{OL}	Low-level output voltage	VDD=3V, I_{OL} =-10mA			VSS +0.4	
		VDD=5V, I_{OL} =-15mA			VSS +0.4	

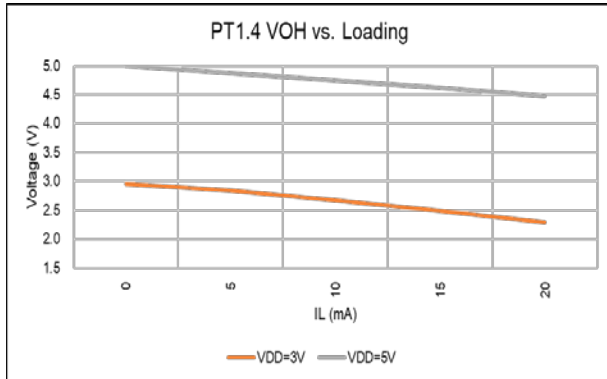


Figure 6.5-1 PT1.4 VOH vs. Loading

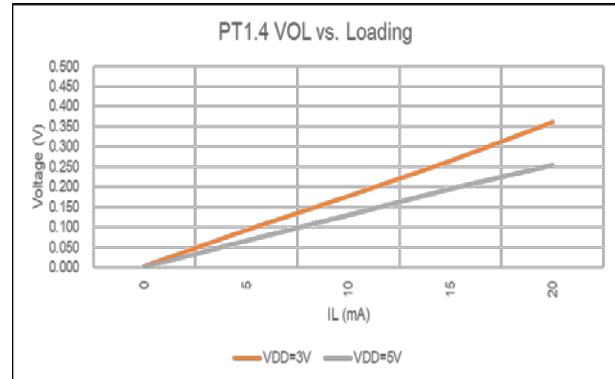


Figure 6.5-2 PT1.4 VOL vs. Loading

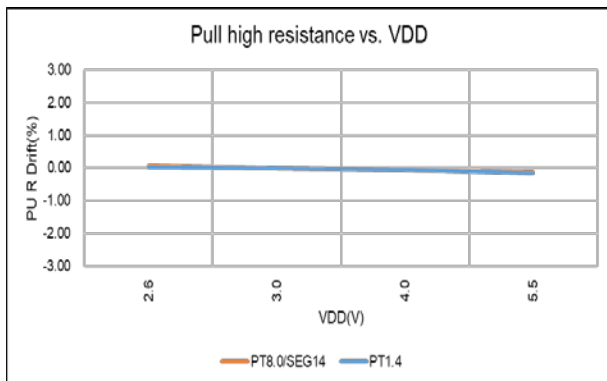


Figure 6.5-3 Pull high resistance vs. VDD

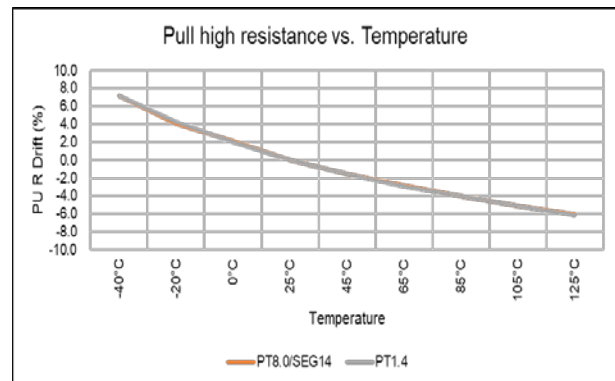


Figure 6.5-4 Pull high resistance vs. Temperature

6.6. Reset(Brownout, Low Voltage Detect)

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	unit
BOR1	Pulse length needed to accepted reset internally, t_{d-LVR1}		2			uS
	VDD Start Voltage to accepted reset internally (L→H), V_{HYS1}		1.6	1.8	2.0	V
	BOR1 current, I_{BOR1}			0.4		uA
	Temperature Drift			5		%
LVD	Operation current, I_{LVD}			10		uA
	External input voltage to compare reference voltage		1.15	1.2	1.25	V
	Compare reference voltage temperature drift	TA = -40°C ~ 85 °C		50		ppm/°C
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1110b		-0.1	4.0	+0.1	V
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1101b			3.6		
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1100b			3.3		
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1011b			3.0		
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1010b			2.9		
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1001b			2.8		
	Detect VDD voltage rang by user option, VSVS VLDS[3:0]=1000b			2.7		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0111b		2.6				

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Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0110b	2.5		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0101b	2.4		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0100b	2.3		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0011b	2.2		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0010b	2.1		
Detect VDD voltage rang by user option, VSVS VLDS[3:0]=0001b	2.0		

BOR1 : Brownout Reset 1
LVD : Low Voltage Detect

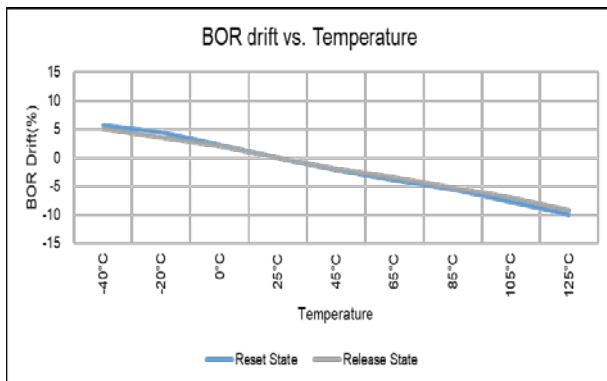


Figure 6.6-1 BOR vs. Temperature

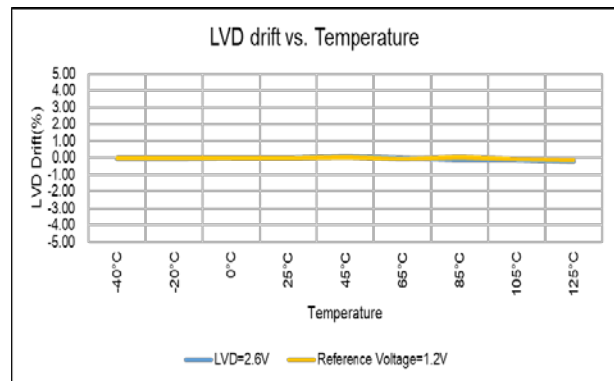


Figure 6.6-2 LVD drift vs. Temperature

6.7. Power System

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
VDDA	VDDA operation current, I_{VDDA}	$I_L = 0\text{mA}$	LDOC[2:0]=000b	20			μA
	Select VDDA output voltage	$I_L = 0.1\text{mA}$, $VDD \geq VDDA + 0.25\text{V}$	LDOC [2:0]=000b	-5%	2.4	+5%	V
			LDOC [2:0]=100b		3.6		V
	Dropout voltage	$I_L = 10\text{mA}$	LDOC [2:0]=000b		500		mV
	Temperature drift	LDOC [2:0]=000b $I_L = 0.1\text{mA}$	TA=-40°C ~85°C	50			PPM/°C
VDD Voltage drift	LDOC [2:0]=000b	VDD=2.2V~5.5V	± 0.2			%/V	
VDDA/2	operation current, I_{ACM}	ENADC[0]=1b,	ENACM [0]=1b	50			μA
	Internal Analog Common Mode Voltage, $V_{ACM}=VDDA/2$		$I_L = 0\mu\text{A}$	VDDA/2			V
	Temperature drift	ENADC[0]=1b,	TA=-40°C ~85°C, ENACM [0]=1b	50			PPM/°C
V12	operation current, I_{V12}	ENADC[0]=1b,	ENV12 [0]=1b	50			μA
	Internal Analog Common Mode Voltage, $V_{ACM}=V12$		$I_L = 0\mu\text{A}$	1.1	1.2	1.3	V

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Temperature drift	ENADC[0]=1b,	TA=-40°C ~85°C, ENV12 [0]=1b	50	PPM/°C
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VDDA : Adjust Voltage Regulator,

ACM : Internal Analog Common Mode Voltage VDDA/2 (No voltage output)

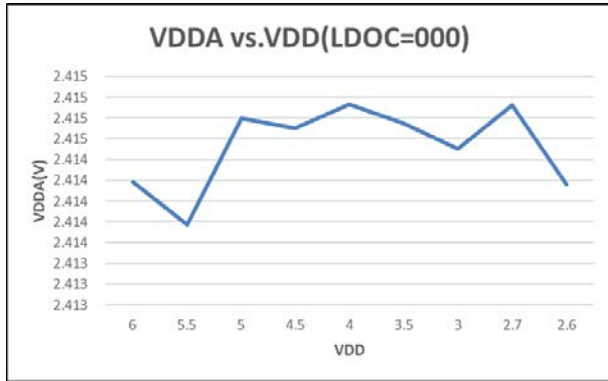


Figure 6.7-1 VDDA Drift vs. VDD

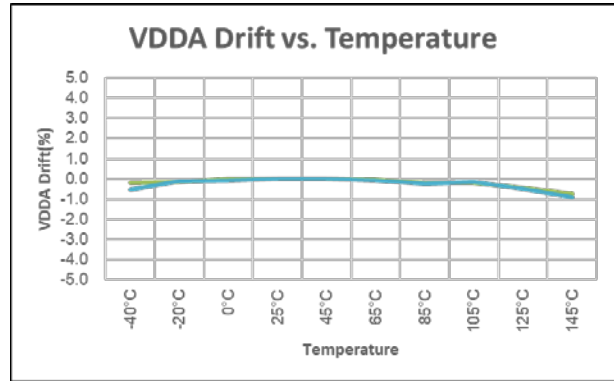


Figure 6.7-2 VDDA Drift vs. Temperature

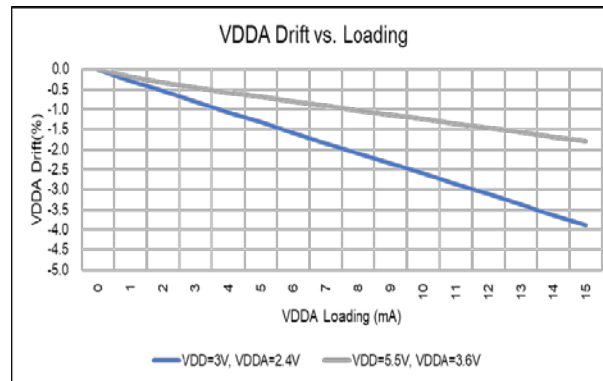


Figure 6.7-3 VDDA Drift vs. Loading

6.8. LCD

TA = 25°C, VDD = 3.3V, CVLCD =4.7uF, unless otherwise noted.

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	unit	
I_{LCD}	Operation supply current with output buffer.(all segment turn on, No load)	ENLCP[0]=1 VDD = 3.0V		5		uA	
VLCD	Supply Voltage at VLCD pin	ENLCP [0]=0	2.4		5	V	
	Embedded Charge Pump output voltage at VLCD pin	VDD = 3.3V, ENLCP [0]=1 CVLCD =4.7uF	LCDV[2:0]=111b	-10%	2.45	+10%	V
			LCDV[2:0]=110b	-10%	2.70	+10%	
			LCDV[2:0]=101b	-10%	2.85	+10%	
			LCDV[2:0]=100b	-10%	3.10	+10%	
			LCDV[2:0]=011b	-10%	3.30	+10%	
			LCDV[2:0]=010b	-10%	4.10	+10%	
LCDV[2:0]=001b	-10%	4.55	+10%				

		(VDD>2.4V mode)			
		LCDV[2:0]=000b (VDD>2.75V)	-10%	5.1	+10%
VDD Voltage drift	ENLCP [0]=1, CVLCD =4.7uF, LCDV[2:0]>010b, VDD=2.2V~ 5.5V; LCDV[2:0]=001b, VDD>2.4V; LCDV[2:0]=000b, VDD>2.75V;		4	%/V	
Z _{LCD}	Output impedance with LCD buffer	f _{LCD} =128Hz, VLCD=3.05V	10	k Ω	

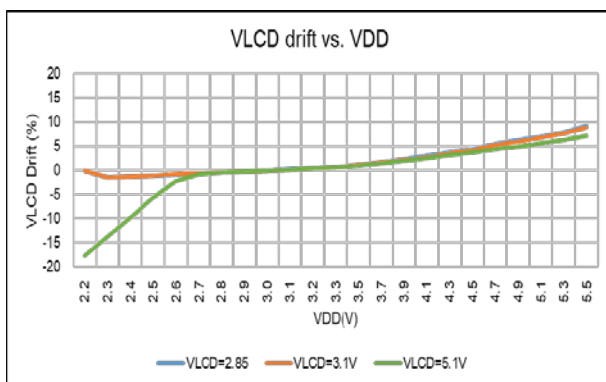


Figure 6.8-1 VLCD drift vs. VDD

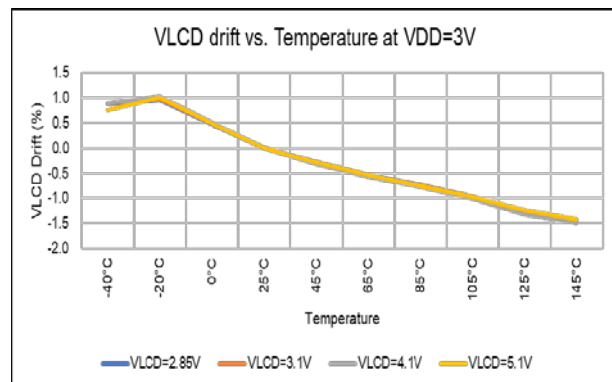


Figure 6.8-2 VLCD drift vs. Temperature at VDD=3V

6.9. $\Sigma\Delta$ ADC, Power Supply and recommended operating conditions

TA = 25°C, VDD = 3.0V, VDDA=2.4V, unless otherwise noted

Sym.	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
V _{SD18}	Supply Voltage at VDDA	ENLDO[0]=0		2.4		5.5	V
f _{SD18}	Modulator sample frequency, ADC_CK			230	921		KHz
	Over Sample Ratio, OSR			64		65536	
I _{SD18}	Operation supply current with-out PGA	ENAD1 [0]=1	GAIN =16, ADC_CK=921KHz		300		uA

6.9.1. PGA, Power Supply and recommended operating conditions

TA = 25°C, VDD = 3.0V, VDDA=2.4V, unless otherwise noted

Sym.	Parameter	Test Conditions		Min	Typ.	Max.	Unit
V _{PGA}	Supply Voltage at VDDA	ENLDO [0]=0		2.4		5.5	V
I _{PGA}	Operation supply current	PGAGN[1:0]=<11>			450		uA
G _{PGA}	Gain temperature drift	TA = -40°C ~ 85°C	GAIN=128		14		ppm/°C

6.9.2. $\Sigma\Delta$ ADC, performance

TA = 25°C, VDD = 3.6V, VDDA=2.4V, V_{VR}= AI2(short to VDDA)/2

GAIN=16 with PGA=8, f_{SD18}=921KHz, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
INL	Integral Nonlinearity(INL)	VDDA=2.4V, VVR= AI2/2, $\Delta SI = \pm 450mV$		± 0.003	± 0.01	%FSR
	No Missing Codes ³	ADC_CK=921KHz, OSR[3:0]=0000b	23			Bits
G _{SD18}	Temperature drift Gain x16	TA = -40°C ~ 85°C		10		ppm/°C
E _{OS}	Offset error of Full Scale Rang input voltage range with Chopper without PGA	$\Delta AI = 0V$ $\Delta VR = 1.2V$ DCSET[3:0]=<0000> * ΔAI is external short	Gain=2		1	%FSR
	Offset temperature drift with chopper without PGA		GAIN=1		2	uV/°C
			GAIN=2		1	
			GAIN=4		0.5	
Offset temperature drift with chopper	GAIN=16		0.15			
CM _{SD18}	Common-mode rejection	V _{CM} =0.7V to 1.7V, V _{VR} = 1.0V, without PGA	V _{SI} =0V, GAIN=1		90	dB
			V _{SI} =0V, GAIN=16		75	dB
PSRR	DC power supply rejection	VDDA=3.0V $\Delta V_{DDA} = \pm 100mV$, V _{VR} =1.0V, V _{SI} =1.2V, V _{SIr} =1.2V,	GAIN=1 PGA=off		75	dB
			GAIN=16 PGA=8			dB

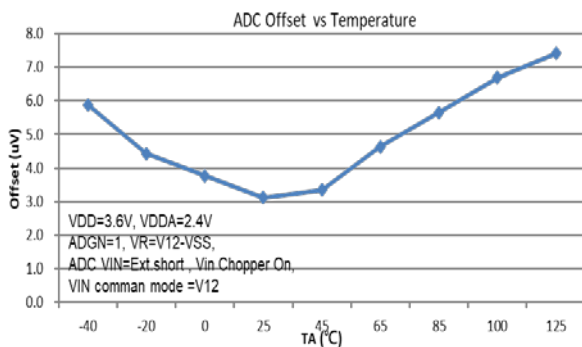


Figure 6.9-1 ADC Offset drift with Temperature (Gain=1)

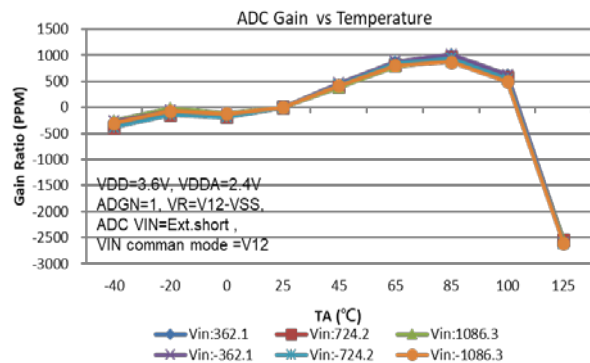


Figure 6.9-2 ADC Gain drift with Temperature (Gain=1)

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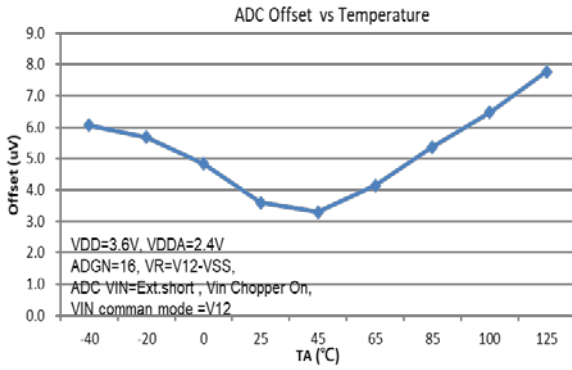


Figure 6.9-3 ADC Offset drift with Temperature (Gain=16)

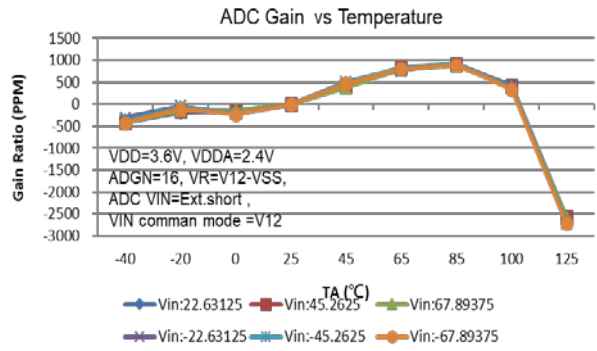


Figure 6.9-4 ADC Gain drift with Temperature (Gain=16)

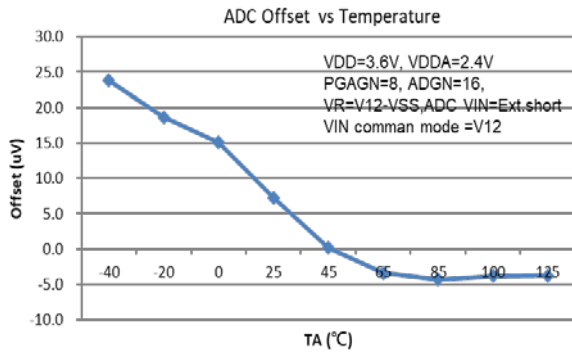


Figure 6.9-5 Offset drift with Temperature (Gain=128)

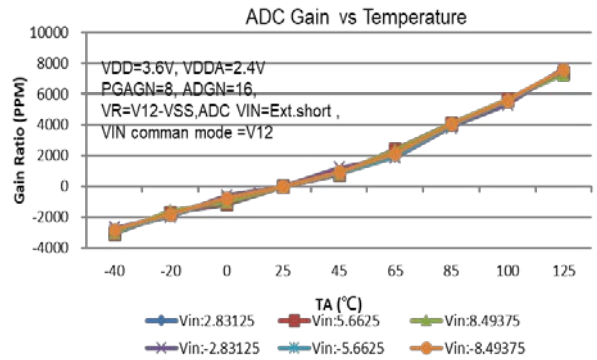


Figure 6.9-6 ADC Gain drift with Temperature (Gain=128)

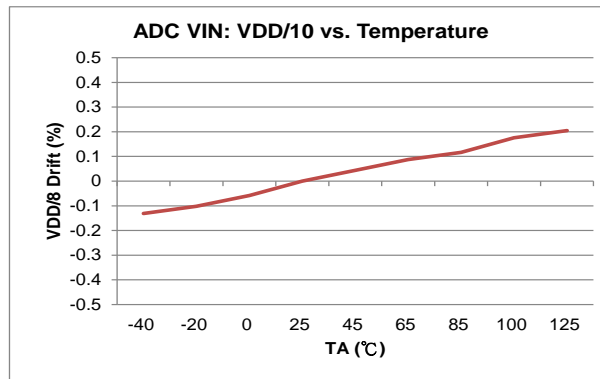


Figure 6.9-7 VDD/10 drift with Temperature

6.9.3. Σ ADC Noise Performance

Provide important input noise specifications for the Σ ADC. Table 6.9-1 below shows the typical noise specification table and the relationship between Gain, Output rate, and differential maximum input voltage., sampling 1024 datas.

<i>ENOB(RMS) with OSR/GAIN at A/D Clock=921KHz, VDD=3.6V, VDDA=2.4V, VREF=1.2V</i>																
Max. Vin(mV) =0.9VREF ⁽¹⁾	OSR				64	128	256	512	1024	2048	4096	8196	16384	32768	65536	
	Output rate(Hz)				15625	7813	3906	1953	977	488	244	122	61	28	14	
	Gain	=	PGAGN	x	ADGN											
±1080	1	=	off	x	1	14.05	15.24	15.8	16.24	16.65	17.03	17.52	18.09	18.56	18.98	19.52
±270	4	=	off	x	4	14.09	15.14	15.59	16.02	16.6	16.87	17.31	17.82	18.29	18.74	19.1
±68	16	=	off	x	16	11.95	14.88	15.39	15.94	16.47	16.81	17.21	17.73	18.13	18.6	19.02
±135	8	=	8	x	1	13.67	15.14	15.6	16.04	16.47	16.88	17.35	17.87	18.42	18.87	19.34
±8.5	128	=	8	x	16	11.61	12.63	13.13	13.55	14.11	14.47	14.92	15.36	15.96	16.46	16.92

(1) Max. Vin(mV) is the max. input voltage single end to ground(VSS)

<i>RMS(uV) with OSR/GAIN at A/D Clock=921KHz, VDD=3.6V, VDDA=2.4V, VREF=1.2V</i>																
Max. Vin(mV) =0.9VREF ⁽¹⁾	OSR				64	128	256	512	1024	2048	4096	8196	16384	32768	65536	
	Output rate(Hz)				15625	7813	3906	1953	977	488	244	122	61	28	14	
	Gain	=	PGAGN	x	ADGN											
±1080	1	=	off	x	1	142.74	62.37	42.43	31.17	23.40	18.04	12.83	8.65	6.22	4.65	3.20
±270	4	=	off	x	4	34.62	16.74	12.22	9.06	6.06	5.03	3.71	2.61	1.88	1.38	1.08
±68	16	=	off	x	16	38.02	4.99	3.52	2.41	1.66	1.32	0.99	0.69	0.53	0.38	0.28
±135	8	=	8	x	1	23.17	8.36	6.06	4.47	3.33	2.50	1.80	1.26	0.86	0.63	0.46
±8.5	128	=	8	x	16	6.05	2.97	2.11	1.58	1.07	0.83	0.61	0.45	0.30	0.21	0.15

Table 6.9-1(a) Σ ADC ENOB and RMS Noise Table at VDDA=2.4V

<i>ENOB(RMS) with OSR/GAIN at A/D Clock=1MHz, VDD=3.6V, VDDA=2.4V, VREF=1.2V at High Accuracy Mode</i>																
Max. Vin(mV) =0.9VREF ⁽¹⁾	OSR				64	128	256	512	1024	2048	4096	8196	16384	32768	65536	
	Output rate(Hz)				7813	3906	1953	977	488	244	122	61	31	14	7	
	Gain	=	PGAGN	x	ADGN											
±1080	1	=	off	x	1	14.95	15.76	16.25	16.8	17.13	17.51	17.99	18.51	19	19.61	20.04
±270	4	=	off	x	4	14.94	15.64	16.07	16.52	17.02	17.34	17.83	18.43	18.92	19.39	19.82
±68	16	=	off	x	16	14.75	15.44	15.89	16.46	16.96	17.32	17.79	18.3	18.81	19.22	19.62
±135	8	=	8	x	1	14.94	15.59	16.1	16.59	17.06	17.37	17.89	18.31	18.92	19.37	19.81
±8.5	128	=	8	x	16	12.57	12.89	13.53	13.94	14.48	14.68	15.25	15.85	16.38	16.98	17.49

(1) Max. Vin(mV) is the max. input voltage single end to ground(VSS)

<i>RMS Noise(uV) with OSR/GAIN at A/D Clock=1MHz, VDD=3.6V, VDDA=2.4V, VREF=1.2V at High Accuracy Mode</i>																
Max. Vin(mV) =0.9VREF ⁽¹⁾	OSR				64	128	256	512	1024	2048	4096	8196	16384	32768	65536	
	Output rate(Hz)				7813	3906	1953	977	488	244	122	61	31	14	7	
	Gain	=	PGAGN	x	ADGN											
±1080	1	=	off	x	1	76.21	43.47	30.92	21.16	16.80	12.95	9.29	6.45	4.61	3.01	2.24
±270	4	=	off	x	4	19.21	11.84	8.76	6.40	4.53	3.63	2.59	1.71	1.22	0.88	0.65
±68	16	=	off	x	16	5.46	3.39	2.48	1.68	1.18	0.92	0.67	0.47	0.33	0.25	0.19
±135	8	=	8	x	1	9.62	6.11	4.30	3.06	2.20	1.78	1.24	0.93	0.61	0.44	0.33
±8.5	128	=	8	x	16	3.11	2.49	1.59	1.20	0.83	0.72	0.48	0.32	0.22	0.15	0.10

Table 6.9-1(b) High Accuracy Mode, Σ ADC ENOB and RMS Noise Table at VDDA=2.4V

The RMS Noise are referred to the input. The Effective Number of Bits (ENOB(RMS Bit)) is defined as:

$$\text{ENOB(RMS)} = \frac{\ln\left(\frac{\text{FSR}}{\text{RMS Noise}}\right)}{\ln(2)}$$

$$\text{RMS Noise} = \frac{\left(2 \times \text{VREF} \times \sqrt{\sum_{k=1}^{1024} (\text{ADO}[k] - \text{Average})^2}\right)}{2^{23}}$$

Where FSR (Full - Scale Range) = $2 \times \text{VREF}/\text{Gain}$.

$$\text{Average} = \frac{\sum_{k=1}^{1024} (\text{ADO}[k])}{1024}$$

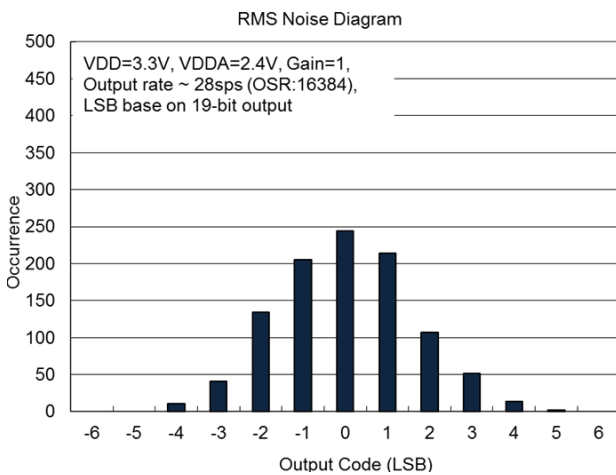


Figure 6.9-8 RMS Noise Diagram

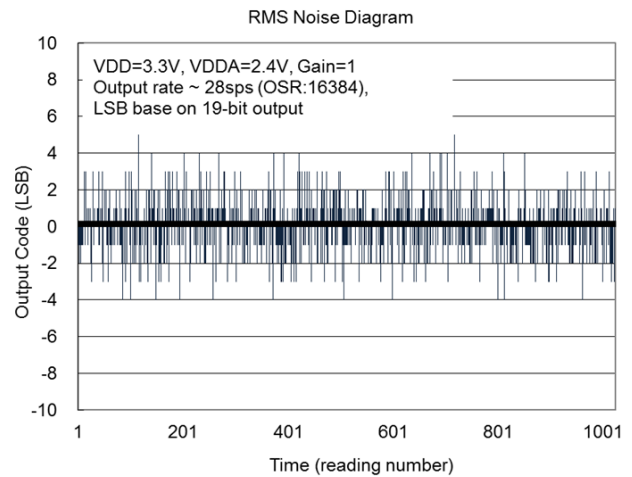


Figure 6.9-9 Output Code Diagram

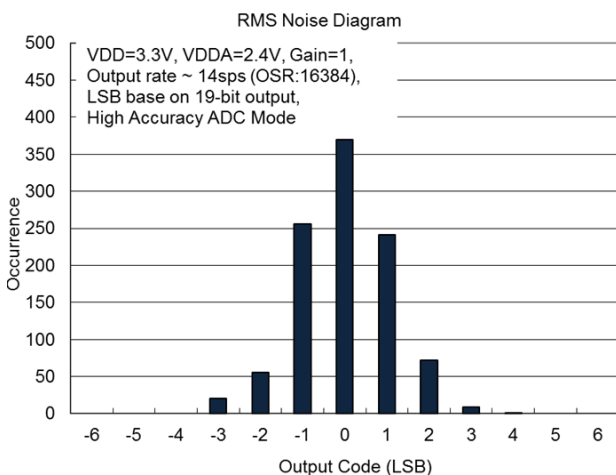


Figure 6.9-10 RMS Noise Diagram

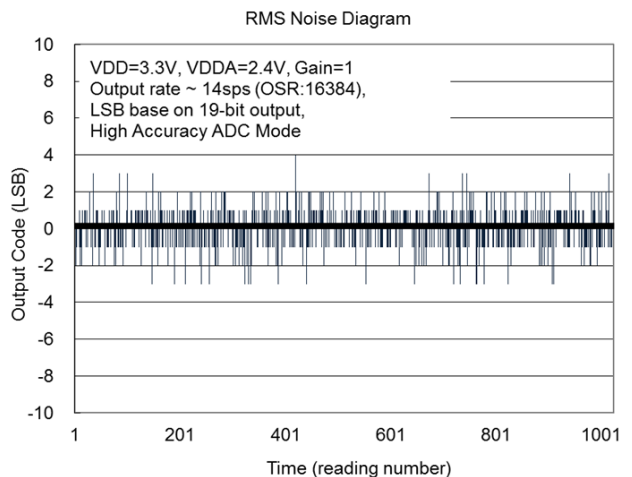


Figure 6.9-11 Output Code Diagram

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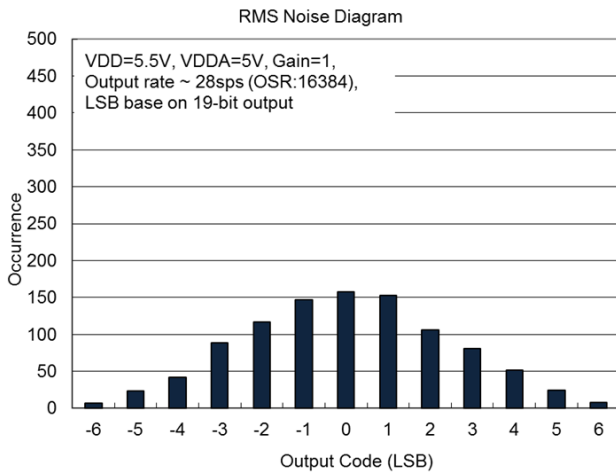


Figure 6.9-12 RMS Noise Diagram

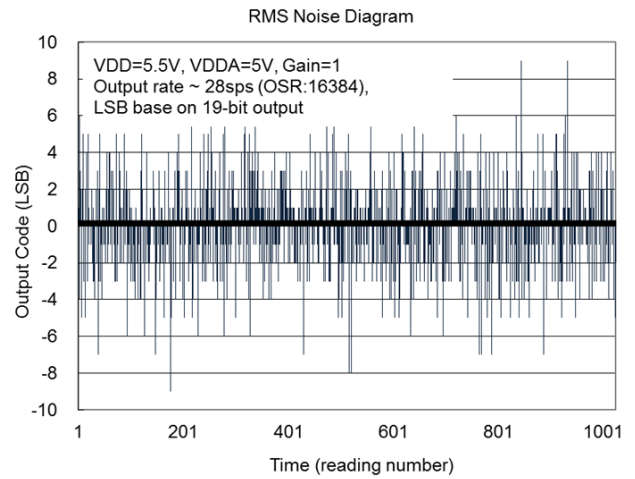


Figure 6.9-13 Output Code Diagram

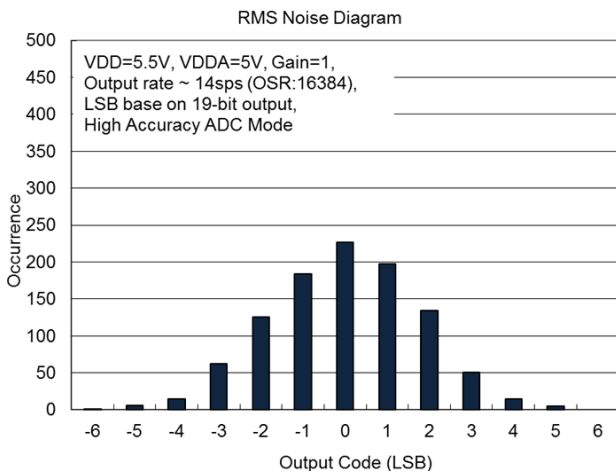


Figure 6.9-14 RMS Noise Diagram

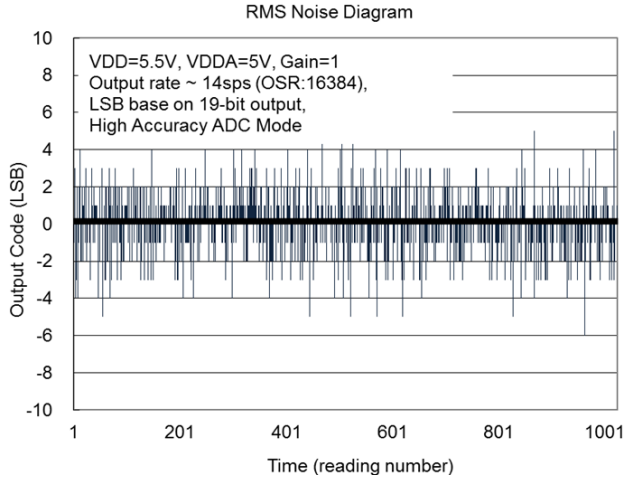


Figure 6.9-15 Output Code Diagram

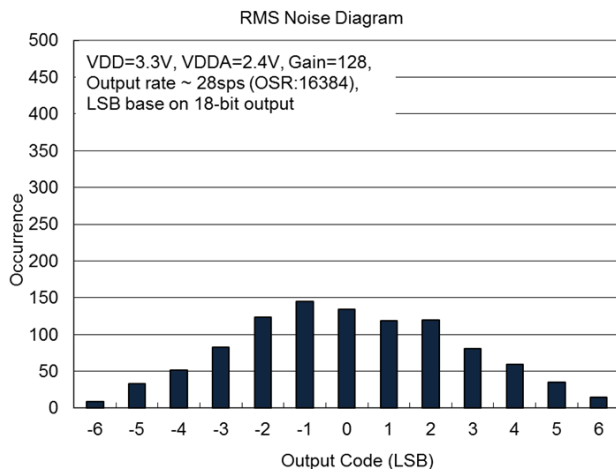


Figure 6.9-16 RMS Noise Diagram

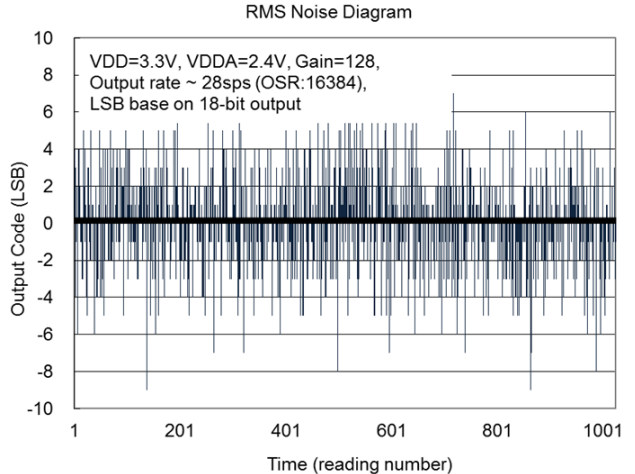


Figure 6.9-17 Output Code Diagram

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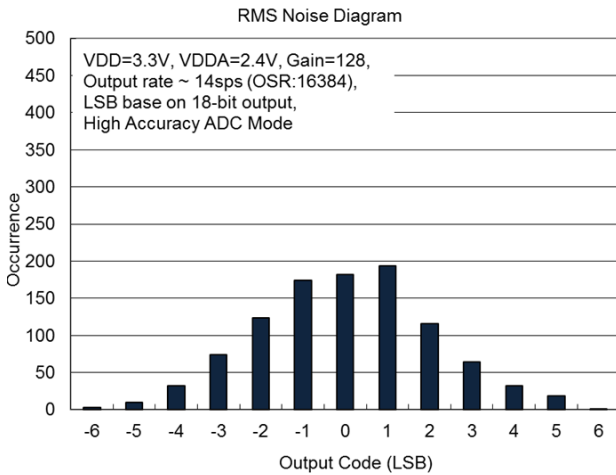


Figure 6.9-18 RMS Noise Diagram

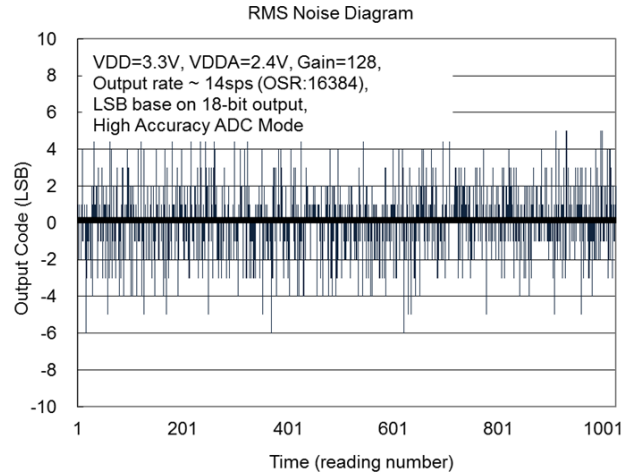


Figure 6.9-19 Output Code Diagram

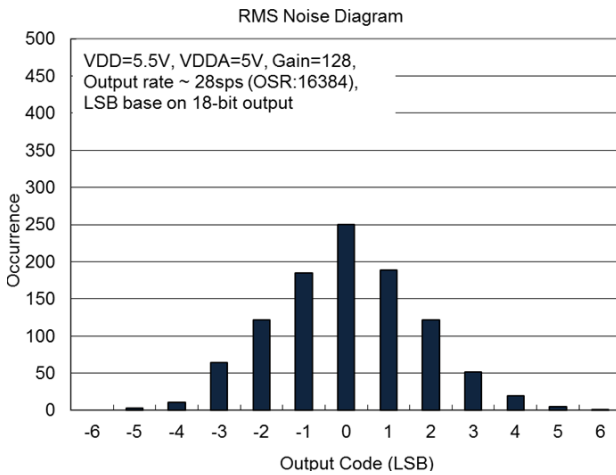


Figure 6.9-20 RMS Noise Diagram

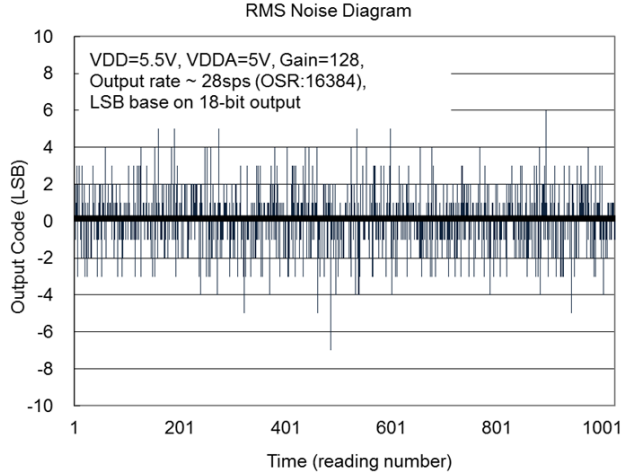


Figure 6.9-21 Output Code Diagram

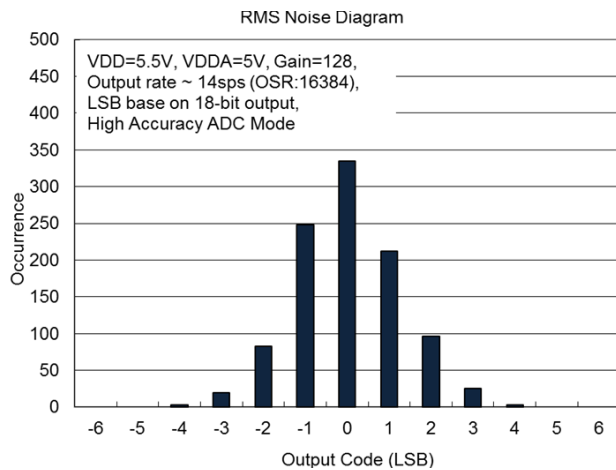


Figure 6.9-22 RMS Noise Diagram

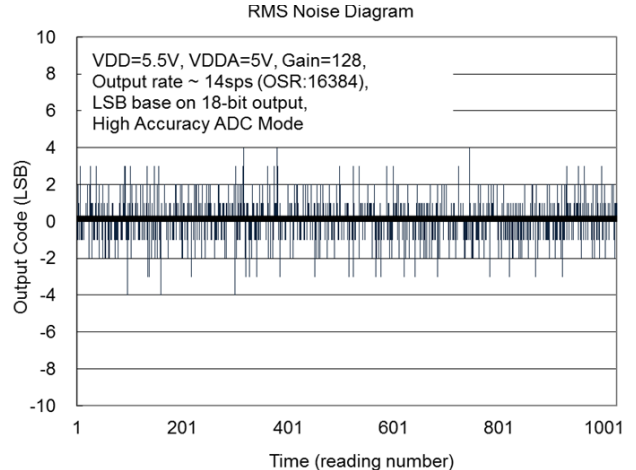


Figure 6.9-23 Output Code Diagram

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Embedded High Resolution $\Sigma\Delta$ ADC 8-Bit RISC-like Mixed Signal Microcontroller

6.9.4. $\Sigma\Delta$ ADC, Temperature Sensor

TA = 25°C, VDD = 3.0V, VDDA=2.4V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
TC _S	Sensor temperature drift			1.7		mV/°C
TC _{ERR}	One point calibrate error temperature	Calibration at 25°C of -40°C ~85°C		±2		°C

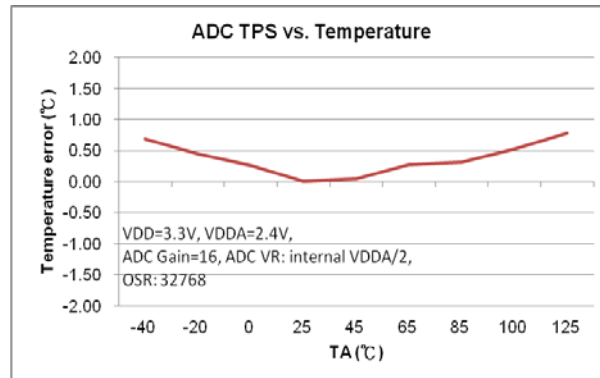


Figure 6.9-24 ADC Temperature Error

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Embedded High Resolution $\Sigma\Delta$ ADC
8-Bit RISC-like Mixed Signal Microcontroller



6.10. Build-In EPROM(BIE)

TA = 25°C, VDD = 3.0V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V _{BIE}	Supply Voltage at VPP PIN		7.5	7.75	8.0	V
I _{BIE}	Operation supply current				6.3	mA
V _{SS}	Supply Voltage			0		V

When connecting to the external VBIE power source to program the BIE block, users can use the instruction to program the words one by one into the BIE block.

6.11. Build-In EPROM(BIE) Low voltage control circuit

TA = 25°C, VDD = 3.05V, unless otherwise noted

Sym.	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
T _O	Operation temperature range		0	25	40	°C
V _{DD}	Operation supply Voltage		2.75		5.5	V
V _{SS}	Supply Voltage			0		V

When the 2.75V low voltage programming control circuit is activated, users can program the BIE block without connecting to the external VBIE power source.

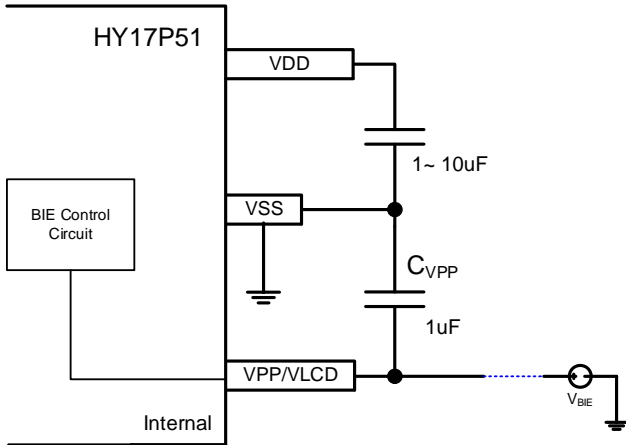


Figure 6.11-1 BIE typical application circuit

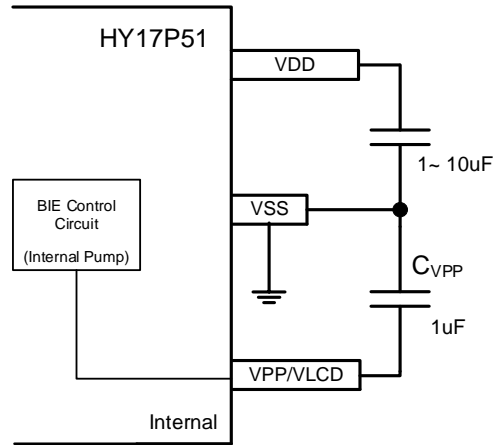


Figure 6.11-2 Use low voltage control circuit

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Embedded High Resolution Σ ADC
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7. Ordering Information

Device No. ¹	Package Type	Pins	Package Drawing		Code ²	Shipment Packing Type	Unit Q'ty	Material Composition	MSL ³
			N	S					
HY17P51-NS32	QFN	32	N	S32	000	Tape & Reel	5000	Green ⁴	MSL-3
HY17P51-N016	QFN	16	N	016	000	Tape & Reel	5000	Green ⁴	MSL-3

¹ Device No.: Model No. – Package Type Description – Code (Blank Code/ Standard/Customized Programming Code)

Ex: You request blank code in QFN32 package. The device No. will be HY17P51-NS32, and please clearly indicate the shipment packing type when placing orders.

Ex: Your customized programming code is 008 and you require products in QFN32 package. The device No. will be HY17P51-NS32-008. and please clearly indicate the shipment packing type when placing orders.

Ex: You request blank code in QFN16 package. The device No. will be HY17P51-N016, and please clearly indicate the shipment packing type when placing orders.

Ex: Your customized programming code is 009 and you require products in QFN16 package. The device No. will be HY17P51-N016-009. and please clearly indicate the shipment packing type when placing orders.

² Code

“001”~ “999” is standard or customized programming code. Blank code does not have these numbers.

³ MSL:

The Moisture Sensitivity Level ranking conforms to IPC/JEDEC J-STD-020 industry standard categorization. The products are processed, packed, transported and used with reference to IPC/JEDEC J-STD-033.

⁴ Green (RoHS & no Cl/Br):

HYCON products are Green products that compliant with RoHS directive and are Halogen free (Br<900ppm or Cl<900ppm or (Br+Cl)<1500ppm) °

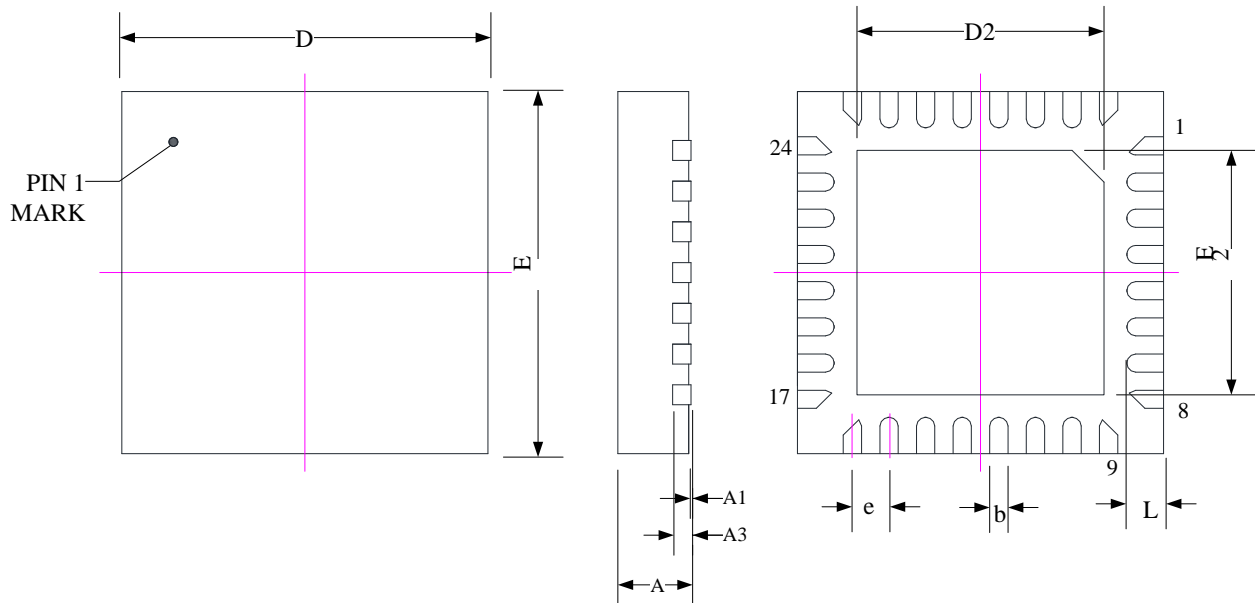
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8-Bit RISC-like Mixed Signal Microcontroller

8. Package Information

8.1. QFN32(NS32)

8.1.1. Package Dimensions QFN32(4x4x0.55)



SYMBOLS	MIN	NOM	MAX
A	0.50	0.55	0.60
A1	0.00	0.02	0.05
A3	0.15 REF.		
b	0.15	0.20	0.25
D	3.90	4.00	4.10
E	3.90	4.00	4.10
D2	2.65	2.70	2.75
E2	2.65	2.70	2.75
L	0.25	0.30	0.35
e	0.40 BASIC		

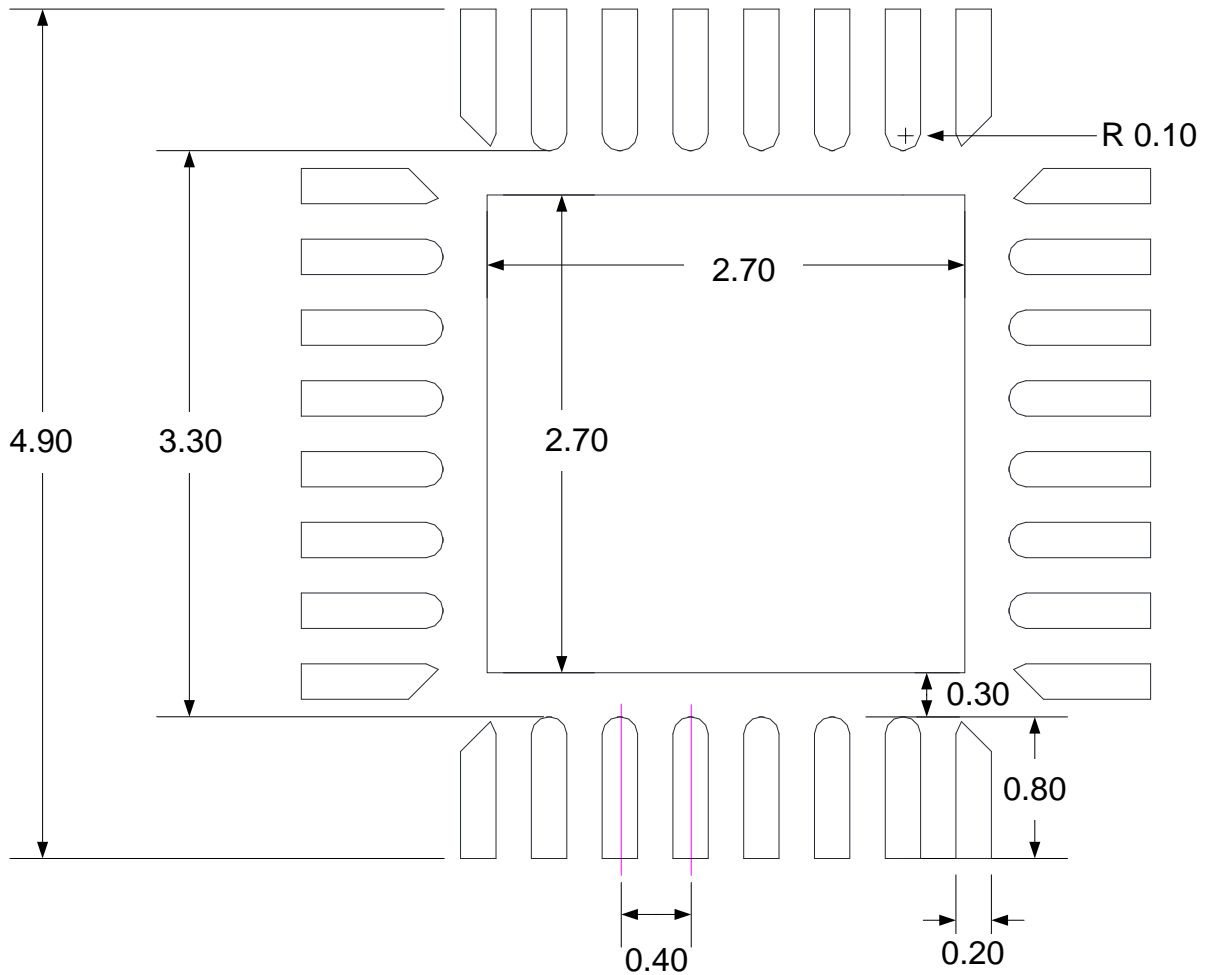
Note:

1. All dimensions refer to JEDEC OUTLINE MO-220.
2. Do not include Mold Flash or Protrusions.
3. Unit: mm.
4. https://www.hycontek.com/hy_mcu/QFN_DFN_PCB_EN.pdf

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8.1.2. Land Pattern Design Recommendations



Note:

1. Publication IPC-7351 is recommended for alternate designs.
2. Unit: mm.
3. https://www.hycontek.com/hy_mcu/QFN_DFN_PCB_EN.pdf

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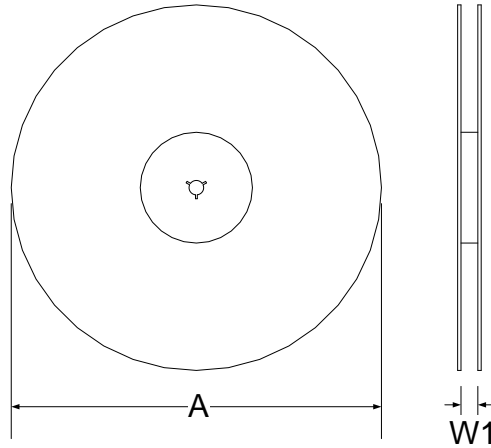
Embedded High Resolution $\Sigma\Delta$ ADC
8-Bit RISC-like Mixed Signal Microcontroller



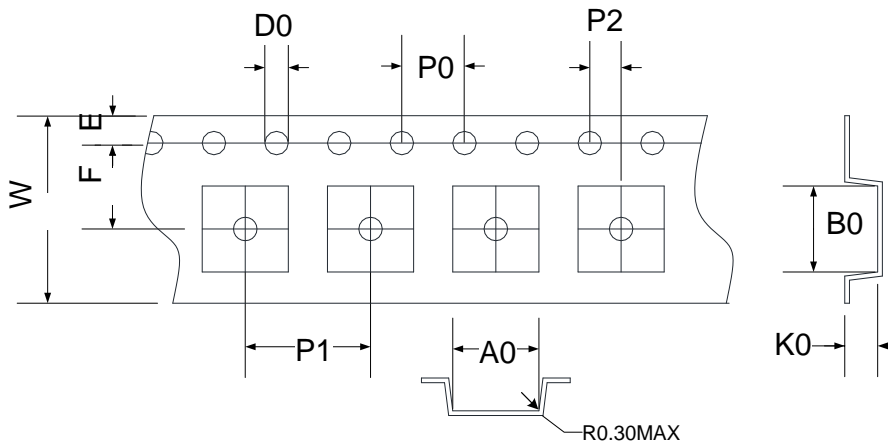
8.1.3. Tape & Reel Information

8.1.3.1. Reel Dimensions

Unit: mm



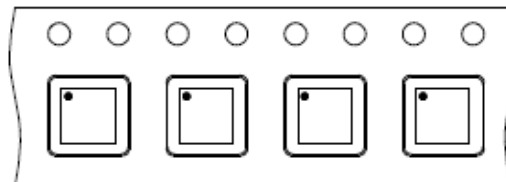
8.1.3.2. Carrier Tape Dimensions



SYMBOLS	Reel Dimensions		Carrier Tape Dimensions										
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W	
Spec.	330	12.5	4.35	4.35	1.10	4.00	8.00	2.00	1.75	5.50	1.50	12.00	
Tolerance	+6/-3	+1.5/-0	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.05	±0.10	±0.05	+0.1/-0	±0.30

Note: 10 Sprocket hole pitch cumulative tolerance is ± 0.20 mm.

8.1.3.3. Pin1 direction

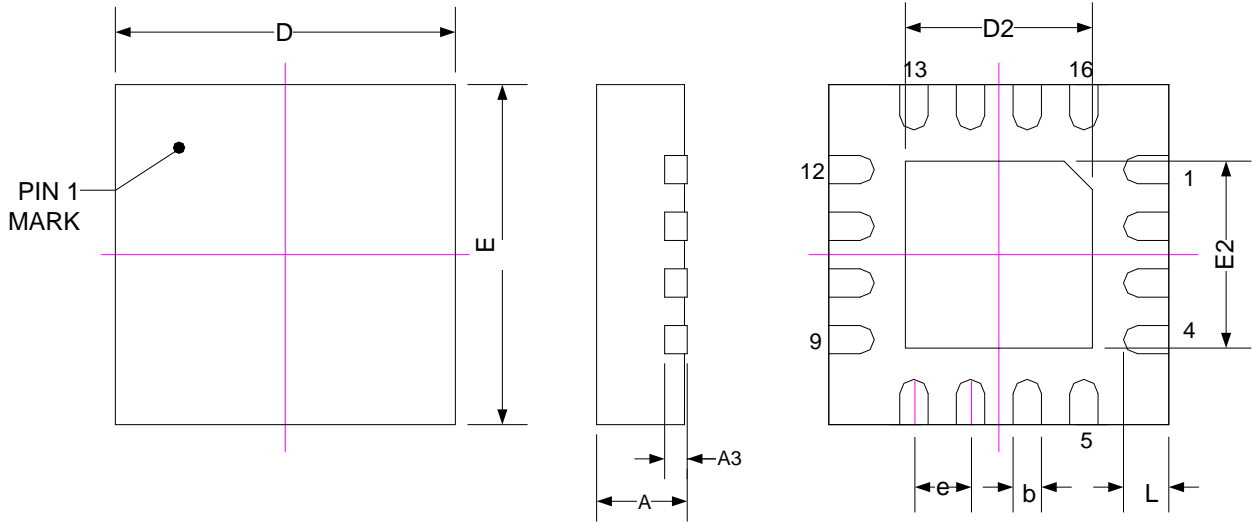


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8.2. QFN16(N016)

8.2.1. Package Dimensions QFN16(3x3x0.75)



SYMBOLS	MIN	NOM	MAX
A	0.70	0.75	0.80
A3	0.203 REF.		
b	0.20	0.25	0.30
D	2.925	3.000	3.075
E	2.925	3.000	3.075
D2	1.625	1.725	1.825
E2	1.625	1.725	1.825
L	0.30	0.35	0.40
e	0.50 BASIC		

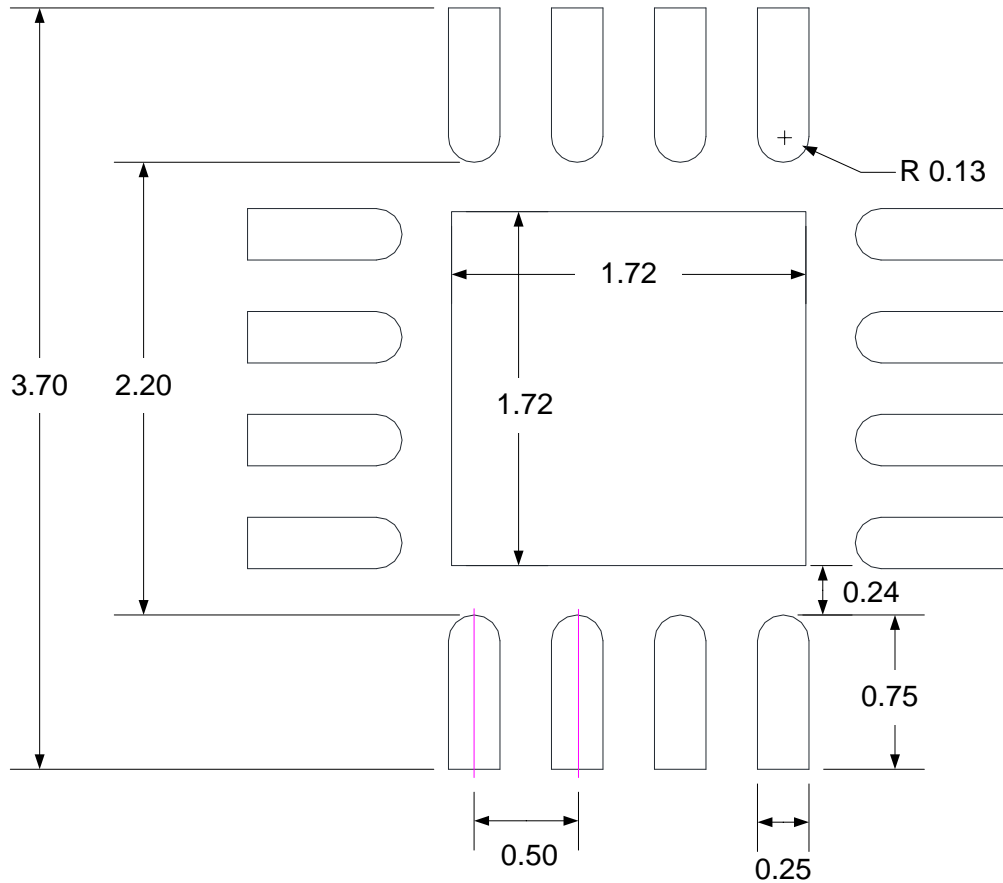
Note:

1. All dimensions refer to JEDEC OUTLINE MO-220.
2. Do not include Mold Flash or Protrusions.
3. Unit: mm.
4. https://www.hycontek.com/hy_mcu/QFN_DFN_PCB_EN.pdf

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8.2.2. Land Pattern Design Recommendations



Note:

1. Publication IPC-7351 is recommended for alternate designs.
2. Unit: mm.
3. https://www.hycontek.com/hy_mcu/QFN_DFN_PCB_EN.pdf

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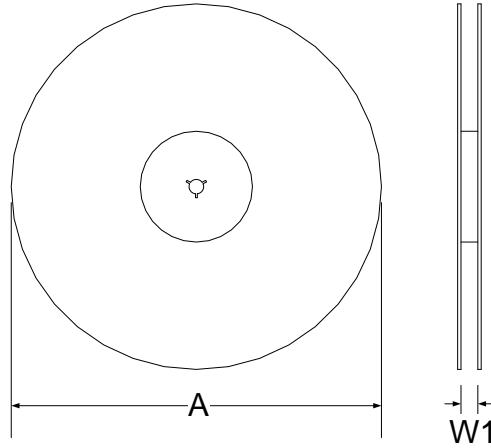
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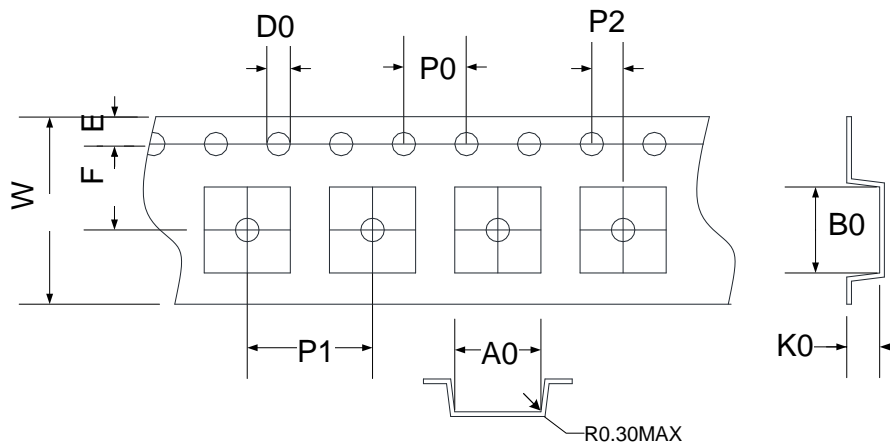
8.2.3. Tape & Reel Information

8.2.3.1. Reel Dimensions

Unit: mm



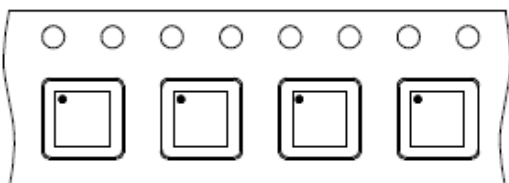
8.2.3.2. Carrier Tape Dimensions



SYMBOLS	Reel Dimensions		Carrier Tape Dimensions										
	A	W1	A0	B0	K0	P0	P1	P2	E	F	D0	W	
Spec.	330	12.5	3.30	3.30	1.10	4.00	8.00	2.00	1.75	5.50	1.50	12.00	
Tolerance	+6/-3	+1.5/-0	±0.10	±0.10	±0.10	±0.10	±0.10	±0.10	±0.05	±0.10	±0.05	+0.1/-0	±0.30

Note: 10 Sprocket hole pitch cumulative tolerance is ± 0.20 mm.

8.2.3.3. Pin1 direction



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9. Revision Record

Major differences are stated thereafter.

Version	Page	Date	Revision Summary
V02	All	2022/08/25	First edition